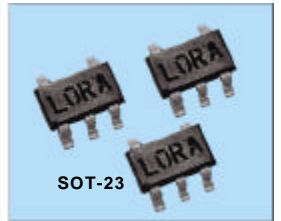
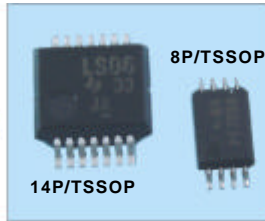
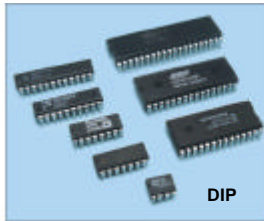


MEMORY IC

EPROM記憶體
可重覆燒錄EPROM
EPROM

詳細產品規格--請點擊www.100y.com.tw



PartNo.	ProductNo.	Manuf.	Description	wordsbits	AccessTime(nS)	ProgramVolt.	Volt.(Vcc)	Size(bits)	Pins/Package
24029	AM27128A-3DC	AMD	EPROM	16K*8		12.5V		128K	DIP/28P
1416	AM27C020-150DC	AMD	2 Megabit (256 K*8-Bit) CMOS EPROM	256K*8	150ns	12.75Vpp	5 V	2M	32P/DIP
18607	AM27C040-120DC	AMD	4 Megabit (512 K*8-Bit) CMOS EPROM	512K*8	120ns	12.75Vpp	5 V	4M	32P/DIP
1418	AM27C040-95PC	AMD	4 Megabit (512 K*8-Bit) CMOS EPROM	512K*8	95ns	12.75Vpp	5 V	4M	32P/DIP
16799	AM27C1024-120DC	AMD	1 Megabit (65K*16-Bit) CMOS EPROM	8K*8	120ns	12.5Vpp	5 V	64K	40P/DIP
18608	AM27C1024-150DC	AMD	1 Megabit (65 K*16-Bit) CMOS EPROM	65K*16	150ns	12.5Vpp	5 V	1M	40P/DIP
18609	AM27C256-90DC	AMD	256 Kbit (32K*8-Bit) CMOS EPROM	32K*8	90ns	12.75Vpp	5 V	256K	28P/DIP
18610	AM27C4096-150DC	AMD	4 Megabit(256K*16-Bit) CMOS EPROM	256K*16	150ns	12.75Vpp	5 V	4M	40P/DIP
18611	AM27C4096-95DC	AMD	4 Megabit(256K*16-Bit) CMOS EPROM	256K*16	90ns	12.75Vpp	5 V	4M	40P/DIP
22451	AM27C512-120DC	AMD	512 Kilobit (64K*8-Bit) CMOS EPROM	64K*8	120ns	12.75Vpp	5 V	512K	28P/DIP
17174	AM27C512-150DC	AMD	512 Kilobit (64K*8-Bit) CMOS EPROM	64K*8	150ns	12.75Vpp	5 V	512K	28P/DIP
18612	AM27C512-90JC	AMD	512 Kilobit (64K*8-Bit) CMOS EPROM	64K*8	150ns	12.75Vpp	5 V	512K	32P/PLCC
18642	AM27H010-70DC	AMD	AM27C010Pin compat	128K*8	70ns	12.5V	5 V	1024K	32P/DIP
18644	AT27C010-45TC	ATMEL	1-Megabit (128K*8)OTP EPROM	128K*8	45ns	14Vpp	5 V	1M	32P/TSOP
22572	CY27C256R-120JC	Cypress	CMOS EPROM	32K*8-Bit	120ns		-0.5-7V	256K	32P/PLCC
18408	HN27C4001G-12	HITACHI	4 MBIT (512KB*8)UVE EPROM	512K*8	120ns	12.5V	5 V	4M	32P/DIP
18666	HT27C512-70J	HOLTEK	CMOS64K*8-Bit OTP EPROM	64K*8	70ns	12.2Vpp	5 V	512K	32P/PLCC
22623	IS27HC010-45W	ISSI	HIGH-SPEED CMOS EPROM	128*8bit	45ns	32P/DIP	-0.6-7V	1M	
14498	M27128AF1	ST(SGS)	NMOS128KBit (16KB*8) UVEPROM	64K	200ns	12.5Vpp	5 V	128K	28P/DIP
1469	M2716	ST(SGS)	NMOS 16 KBIT(2KB*8) UVEPROM	2K*8			5 V	16K	24P/DIP
1470	M2732A-2F1	N.S	NMOS32K(4K*8) UVEPROM	4K*8	200ns	21Vpp	5 V	32K	24P/DIP
15462	M27C1001-10F1	ST(SGS)	UV EPROM AND OTP ROM	128K*8	100ns	12.75Vpp	5 V	1M	32P/DIP
1441	M27C1001-12F1	ST(SGS)	UV EPROM AND OTP ROM	128K*8	120ns	12.75Vpp	5 V	1M	32P/DIP
18670	M27C1001-20F1	ST(SGS)	UV EPROM AND OTP EPROM	128K*8	120ns	12.75Vpp	5 V	1M	32P/DIP
17022	M27C1024-12F1	ST(SGS)	UV EPROM AND OTP EPROM	64K*16	120ns	12.75Vpp	5 V	1M	40P/DIP
14160	M27C1024-15F1	ST(SGS)	UV EPROM AND OTP EPROM	64K*16	150ns	12.75Vpp	5 V	1M	40P/DIP
1440	M27C1024-85F1	ST(SGS)	UV EPROM AND OTP EPROM	64K*16	85ns	12.75Vpp	5 V	1M	40P/DIP
18671	M27C160-100B1	ST(SGS)	UV EPROM AND OTP EPROM	2Mb*8or1Mb*16	100ns	12.75Vpp	5 V	16M	42P/DIP
16607	M27C160-100F1	ST(SGS)	UV EPROM AND OTP EPROM	2Mb*8or1Mb*16	100ns	12.5Vpp	5 V	16M	42P/DIP
18649	M27C160-120F1	ST(SGS)	UV EPROM AND OTP EPROM	2Mb*8or1Mb*16	120ns	12.75Vpp	5 V	16M	42P/DIP
12839	M27C160-90F1	ST(SGS)	UV EPROM AND OTP EPROM	2Mb*8or1Mb*16	90ns	12.75Vpp	5 V	16M	42P/DIP
18650	M27C2001-10F1	ST(SGS)	UV EPROM AND OTP ROM	256K*8	100ns	12.75Vpp	5 V	2M	32P/DIP
1443	M27C2001-12F1	ST(SGS)	UV EPROM AND OTP ROM	256K*8	120ns	12.75Vpp	5 V	2M	32P/DIP
15209	M27C2001-15C6	ST(SGS)	OTP ROM	256Kb*8	150ns	12.75Vpp	5 V	2M	32P/PLCC
18651	M27C2001-15F1	ST(SGS)	UV EPROM AND OTP ROM	256K*8	150ns	12.75Vpp	5 V	2M	32P/DIP
18652	M27C2001-15F6	ST(SGS)	UV EPROM AND OTP ROM	256K*8	150ns	12.75Vpp	5 V	2M	32P/DIP
18653	M27C256B-10B6	ST(SGS)	UV EPROM AND OTP EPROM	32K*8	100ns	12.75Vpp	5 V	256K	28P/DIP
1444	M27C256B-10F1	ST(SGS)	UV EPROM AND OTP EPROM	32K*8	100ns	12.75Vpp	5 V	256K	28P/DIP
18654	M27C256B-12F6	ST(SGS)	UV EPROM and OTP EPROM	32K*8	120ns	12.75Vpp	5 V	256K	28P/DIP
18655	M27C322-100F1	ST(SGS)	UV EPROM and OTP EPROM	2Mb*16	100ns	12.75Vpp	5 V	32M	28P/DIP
1447	M27C4001-10F1	ST(SGS)	UV EPROM AND OTP ROM	512K*8	100ns	12.75Vpp	5 V	4M	32P/FDIP
19590	M27C4001-12F1	ST(SGS)	UV EPROM AND OTP ROM	512K*8	120ns	12.75Vpp	5 V	4M	32P/FDIP
12956	M27C4002-10F1	ST(SGS)	UV EPROM and OTP EPROM	256K*16	100ns	12.75Vpp	5 V	4M	40P/DIP
1449	M27C4002-12F1	ST(SGS)	UV EPROM AND OTP ROM	256K*16	120ns	12.75Vpp	5 V	4M	40P/DIP
18656	M27C4002-80XF1	ST(SGS)	UV EPROM AND OTP ROM	256K*16	120ns	12.75Vpp	5 V	4M	40P/DIP
12214	M27C512-10F1	ST(SGS)	UV EPROM AND OTP EPROM	64K*8	100ns	12.75Vpp	5 V	512K	28P/FDIP
12215	M27C512-12F1	ST(SGS)	UV EPROM AND OTP EPROM	64K*8	120ns	12.75Vpp	5 V	512K	28P/FDIP
18657	M27C512-20B1	ST(SGS)	UV EPROM AND OTP EPROM	64K*8	200ns	12.75Vpp	5 V	512K	28P/DIP
1450	M27C801-100F1	ST(SGS)	UV EPROM AND OTP EPROM	1M*8	100ns	12.75Vpp	5 V	8M	32P/DIP
18658	M27C801-120F1	ST(SGS)	UV EPROM AND OTP EPROM	1M*8	120ns	12.75Vpp	5 V	8M	32P/DIP
19329	M51957BL	MITSUBISHI					2-17V		5P5T
17150	M5M27C102K-12	MITSUBISHI	EPROM	128K*8	120ns		12.5V	1M	40P/DIP



MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	words/bits	Access time(nS)	Program Volt	Volt.(Vcc)	Size(bits)	Pins/Package
19375	MB8516	FUJITSU							DIP
22743	MX27C1000QC-15	MXIC	CMOS EPROM	128K*8	150nS	12.5V	5V	1M	32P/PLCC
22744	MX27C256QC-15	MXIC	CMOS EPROM	32K*8	150nS	12.5V	5V	256K	32P/PLCC
1458	MX27C4100MC-12	MXIC	CMOS EPROM	512K*8	120ns	12.5Vpp	5V	4M	40P/SOP
22745	MX27C512PC-55	MXIC	CMOS EPROM	64K*8	120nS	12.5V	5V	512K	28P/DIP
22747	MX27C512QC-55	MXIC	CMOS EPROM	64K*8	55nS	12.5V	5V	512K	32P/PLCC
22748	MX27C512QC-90	MXIC	CMOS EPROM	64K*8	90nS	12.5V	5V	512K	32P/PLCC
22749	MX27C8000QC-12	MXIC	CMOS EPROM	1M*8	120nS	12.5V	5V	8M	32P/PLCC
22750	MX27L2000PC-15	MXIC	CMOS EPROM	256K*8	150nS	12.5V	2.7~3.6V	2M	32P/DIP
23226	NM27C256Q150	N.S	可重複燒錄EPROM	32K*8	150nS	12.75Vpp	5V	256K	DIP
1465	NM27C256Q90	Fairchild	High Performance CMOS EPROM	32K*8	90nS	12.75Vpp	5V	256K	28P/DIP
23599	NM27C256V150	N.S	High Performance CMOS EPROM	32K*8	150ns		5V ±0%	256K	32P/PLCC
18672	NM27C256V200	N.S	High Performance CMOS EPROM	32K*8	200ns	12.75Vpp	5V	262,144	32P/PLCC
1467	NM27C512Q150	N.S	EPROM 64K*8 DIP	64K*8	150ns	12.75Vpp	5V	512K	28P/DIP
18673	P27C220-150V05	INTEL	2M-BIT [256Kx8/128x16] CMOS EPROM	256K*8 or 128*16	150ns	12.5Vpp	5V	2M	40P/DIP
18674	TMS27C020-12JE	T.I.	Programmable Read-only Memories	256K*8	120ns	12.75Vpp	5V	2M	32P/DIP
1475	TMS27C020-12JL	T.I.	Programmable Read-only Memories	256K*8	120ns	12.75Vpp	5V	2M	32P/DIP
18675	TMS27C020-15JL	ST(SGS)	Programmable Read-only Memories	256K*8	150ns	12.75Vpp	5V	2M	32P/DIP
18676	TMS27C256-12JL	ST(SGS)	READ-ONLY MEMORY	32K*8	120ns	12.5Vpp	5V	256K	32P/DIP
3196	TMS27C512-10JL	T.I.	Programmable Read-only Memories	64K*8	100nS	12.75Vpp	5V	512K	28P/DIP
18677	TMS27PC128-1NL	ST(SGS)	READ-ONLY MEMORY	16K*8	150ns	12.5Vpp	5V	128K	28P/DIP
1484	UPD27C1024AD-15	NEC	1M-BIT [128K*8/64K*16] CMOS EPROM	64K*16	150ns	12.75Vpp	5V	1M	40P/DIP
15277	W27C257-10	WINBOND	Electrically Erasable EPROM	32K*8	100nS	12Vpp	5V	256K	28P/DIP
1433	W27C512-45	WINBOND	Electrically Erasable EPROM	64K*8	45ns	12Vpp	5V	512K	28P/DIP
18678	W27C512P-45	WINBOND	Electrically Erasable EPROM	64K*8	45ns	12Vpp	5V	512K	32P/PLCC
23150	W27C512P-70	WINBOND	ELECTRICALLY ERASABLE EPROM	64K*8	70nS		5V	512K	32P/PLCC
16558	W27E010-70	WINBOND	1MElectrically Erasable EPROM	128K*8	70nS	12Vpp	5V	128K*8	32P/DIP
15308	W27E010P-70	WINBOND	1MElectrically Erasable EPROM	128K*8	70nS	12Vpp	5V	1M	32P/PLCC
1487	W27E257-12	WINBOND	32K*8Electrically Erasable EPROM	32K*8	120ns	12Vpp	5V	256K	28P/DIP
1488	W27E512-70	WINBOND	Electrically Erasable EPROM	64K*8	70ns	12Vpp	5V	512K	28P/DIP
14204	MBM27C128-20	FUJITSU	EPROM 16K*8 DIP	16K*8	200ns		5V	128K	28P/DIP

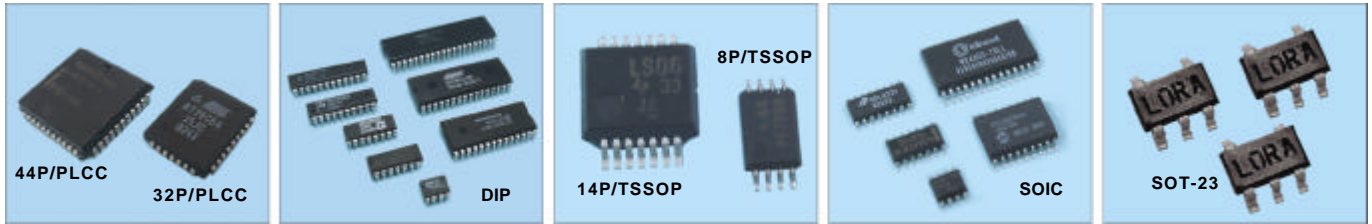
燒錄一次 EPROM OTP EPROM

詳細產品規格--請點擊 www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	words/bits	Access time(nS)	Program Volt	Volt.(Vcc)	Size(bits)	Pins/Package
18606	A276308L-70	AMIC	64K*8 OTP CMOS EPROM	65,536*8bit	70ns	12.75V	5V	512K	32P/PLCC
23517	AM27C010-90DC	AMD	1 Megabit CMOS EPROM		45nS		5V	128K*8Bit	32P/DIP
8508	AM27C256-120JC	AMD	256 Kilobit (32K*8-Bit) CMOS EPROM	32K*8	120nS	12.75Vpp	5V	256K	32P/PLCC
1428	AM27C64-200PC	AMD	64 Kilobit (8K*8-Bit) CMOS EPROM	8K*8	200ns	12.75Vpp	5V	64K	28P/DIP
18643	AT27BV010-90JC	ATMEL	Unregulated Battery-Voltage OTP CMOS EPROM	128K*8	90ns	12.75V	6.25V	1Megabit	32P/PLCC
1434	AT27BV040-15TC	ATMEL	Unregulated Battery-Voltage High-Speed OTP EPROM	512K*8	150ns	14Vpp	5V	4M	32P/TSOP
1425	AT27C010-120JC	ATMEL	1Megabit (128K*8) OTP COMS EPROM	128K*8	120ns	14Vpp	5V	1M	32P/PLCC
1426	AT27C010-15JC	ATMEL	1 Megabit (128K*8) OTP CMOS EPROM	128k*8	150nS	14Vpp	5V	1M	32P/PLCC
1436	AT27C010-45PC	ATMEL	1-Megabit (128K*8) OTP EPROM	128K*8	45ns	14Vpp	5V	1M	32P/DIP
17681	AT27C020-70PC	ATMEL	2-megabit (256K*8) OTP EPROM	256K*8	70ns	14Vpp	5V	2M	32P/DIP
1427	AT27C040-70PC	ATMEL	4-Megabit (512K*8) OTPEPROM	512K*8	70ns	14Vpp	5V	4M	32P/DIP
15274	AT27C080-10JC	ATMEL	8-Megabit (1M*8) OTP EPROM	1M*8	100nS	14Vpp	5V	8M	32P/PLCC
15306	AT27C080-90PI	ATMEL	8-Megabit (1M*8) OTP EPROM	1M*8	90nS	14Vpp	5V	8M	32P/DIP
22458	AT27C2048-90JC	ATMEL	2-Megabit OTP EPROM	128*16	55nS	one-time program-mable	5V	2K	44P/PLCC
18645	AT27C256R-25JC	ATMEL	256K(32K*8) OTP EPROM	32K*8	25ns	14Vpp	5V	256K	32P/PLCC
1432	AT27C512R-12PC	ATMEL	512K(64K*8) OTP EPROM	64K*8	120ns	14Vpp	5V	512K	28P/DIP
22459	AT27C512R-15TC	ATMEL	-512K OTP EPROM	64*8	45nS	-100ms/byte	5V	512K	28P/TSOP
8511	AT27C512R-45JC	ATMEL	512K(64K*8) OTPEPROM	64K*8	45ns	14Vpp	5V	512K	32P/PLCC
18646	AT27C512R-70JC	ATMEL	512K(64K*8) OTPEPROM	64K*8	70ns	14Vpp	5V	512K	32P/PLCC
18647	AT27C512R-70PC	ATMEL	512K(64K*8) OTPEPROM	64K*8	70ns	14Vpp	5V	512K	28P/DIP
22460	AT27C512R-70TC	ATMEL	-512K OTP EPROM	64*8	45nS	-100ms/byte	5V	512K	28P/TSOP
18648	AT27C512R-90JC	ATMEL	512K(64K*8) OTPEPROM	64K*8	90ns	14Vpp	5V	512K	32P/PLCC
23533	AT27C512R-90PC	ATMEL	OTP EPROM	64K*8	45nS		-2~14V	512K	28P/DIP
18664	AT27C512R-90RC	ATMEL	512K(64K*8) OTPEPROM	64K*8	90ns	14Vpp	5V	512K	28P/SOIC
14361	AT27LV010A-12JC	ATMEL	Low Voltage OTP EPROM	128K*8	120nS	14Vpp	5V	1M	32P/PLCC
18665	FM27C256Q120	Fairchild	High Performance CMOS EPROM	32K*8	120ns	12.75Vpp	5V	262,144	28P/DIP
18667	ICE27C512-70DC	ICE	512kbit(64K*8) OTP EPROM	64K*8	70ns	5.5V	12V	512K	28P/DIP
18668	ICE27C512-70PC	ICE	512kbit (64K*8) OTP EPROM	64K*8	70ns	5.5V	12V	512K	32P/PLCC
18669	ICE27C512-70SC	ICE	512kbit (64K*8) OTP EPROM	64K*8	70ns	5.5V	12V	512K	28P/TSOP
14954	M27C256B-12F1	ST(SGS)	UVEPROM and OTP EPROM	32K*8	120ns	12.75Vpp	5V	256K	28P/DIP



MEMORY IC



PartNo.	ProductNo.	Manuf.	Description	words/bits	Access time(nS)	Program Volt	Volt.(Vcc)	Size(bits)	Pins/Package
15273	M27C256B-15C1	ST(SGS)	UV EPROM and OTP EPROM	32K*8	150ns	12.75Vpp	5V	256K	32P/PLCC
23572	M27C256B-80XF1	ST(SGS)	UV EPROM and OTP EPROM	32Kb*8	80ns	12.75V ±0.25V	5V±10%	256K	28P/DIP
1446	M27C256B-90C1	ST(SGS)	UV EPROM and OTP EPROM	32K*8	90ns	12.75Vpp	5V	256K	32P/PLCC
15272	M27C4001-15C1	ST(SGS)	4 Mbit OTP EPROM	512Kb*8	150ns	12.75Vpp	5V	4M	32P/PLCC
22696	M27V256-100F1	ST(SGS)	LOW VOLTAGE EPROM and OTP EPROM	32K*8	100ns	12.75V	3-5.5V	256K	28P/DIP
18659	MX27C1000PC-12	MXIC	OTP EPROM1Mb	128K*8	120ns	12.5Vpp	5V	1M	32P/PLCC
1409	MX27C1000PC-70	MXIC	1M-BIT[128Kx8]CMOSEPROM	128K*8	70ns	12.5Vpp	5V	1M	32P/DIP
18660	MX27C1000QC-45	MXIC	OTP EPROM 1Mb	128K*8	45ns	12.5Vpp	5V	1M	32P/PLCC
1453	MX27C1000QC-90	MXIC	OTP EPROM1Mb	128K*8	90ns	12.5Vpp	5V	1M	32P/PLCC
18661	MX27C2000MC-12	MXIC	2M-BIT [256Kx8] CMOS EPROM	256K*8	120ns	12.5Vpp	5V	2M	32P/SOP
1456	MX27C4000DC-15	MXIC	4M-BIT[512Kx8] CMOS EPROM	512K*8	150ns	12.5Vpp	5V	4M	32P/DIP
18662	N27C256-2	INTEL	256K (32K*8) CMOS EPROM	32K*8	200ns	13Vpp	6.5V	256K	32P/PLCC
18663	NM27C010Q200		High PerformanceCMOSEPROM	128K*8	200ns	12.75Vpp	6.5V	1,048,576	32P/DIP
23621	TMS27C010A-12JL	T.I.	Programmable Read-only Memories		120ns		5V		32P/DIP
22854	TMS27C240-10JL	T.I.	Programmable Read-only Memories	16bits	100ns		5V		40P/DIP
22855	TMS27PC040-12FML	T.I.	Programmable Read-only Memory		120ns		5V	4Mbit	32P/SOP
22856	TMS27PC128-2NE	T.I.	Programmable Read-only Memory	16K*8			5V	128K	28P/DIP
18864	TS80C32X2-MCB	ATMEL	MCU						44P/PLCC
1483	UPD27C1001AGW-15	NEC	EPROM 1M SMD	128K*8	150ns	12.75Vpp	5V	1M	32P/PLCC

EPROM

詳細產品規格--請點擊www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	Organisation	Bus Configuration	Volt.(Vcc)	Size(bits)	Pins/Package
18692	24AA64I/SN	MICRO-CHIP	64K I2C(TM) Serial EEPROM	8K*8	2 wire serial	1.8V	64K	8P/SOIC
1504	24LC02B/P	MICRO-CHIP	Serial EEPROM	256*8	2 wire serial	2.5V	2 K	8P/DIP
17169	24LC02B/SN	MICRO-CHIP	Serial EEPROM	256*8	2 wire serial	2.5V	2 K	8P/SOIC(150mil)
5376	24LC04B/P	MICRO-CHIP	4 K Serial EEPROM	512*8	2 wire serial	2.5-5V	4 K	8P/DIP
18693	24LC08B/SN	MICRO-CHIP	8 K I2C TM Serial EEPROM	4*256*82	2 wire serial	2.5-5.5V	8 K	8P/SOIC
1506	24LC16B/P	MICRO-CHIP	16K 2.5V Serial EEPROM	2K*8	2 wire serial	2.5V	16K	8P/DIP
13756	24LC16B/SN	MICRO-CHIP	16K EEPROM	2K*8	2 wire serial	2.5-5V	16K	8P/SOIC
23170	24LC16BTMI-SN-M2	MICRO-CHIP	Serial EEPROM		2-wire serial	7V		8P/SOIC
5377	24LC21/P	MICRO-CHIP	Dual Mode Serial EEPROM	128*8	2 wire serial	2.5V	1 K	8P/DIP
17682	24LC256-I/P	ATMEL	EEPROM	32K*8	2 wire serial	7V	256K	8P/DIP
23174	24LC256T-I/SM	MICRO-CHIP	CMOS Serial EEPROM		2-wire serial	2.5-5.5V	256Kbit	8P/SOIC
15275	24LC32A/P	MICRO-CHIP	EEPROM	4K*8	2 wire serial	7V	32K	8P/DIP
16646	24LC64I/P	MICRO-CHIP	64K Serial EEPROM	8K*8	2 wire serial	7V	64K	8P/DIP
18695	24LC64I/SN	MICRO-CHIP	64K Serial EEPROM	8K*8	2 wire serial	7V	64K	8P/SOIC(150mil)
22422	93LC46A/SN	MICRO-CHIP	1K Microwire Serial EEPROM	1024bits	3 wire serial	6.5V	128*8bits	8P/SOIC
24671	93LC46B	MICRO-CHIP	EEPROM	64*16bit	3-wire serial	7V	1 K	DIP/8P
16420	93LC46B-I/SN	MICRO-CHIP	1 KMicrowire-Compatible Serial EEPROM	64*16	3 wire serial	7V	1 K	8P/SOIC
18696	93LC46B/SN	MICRO-CHIP	1 K2.5V Microwire Serial EEPROM	128*8or 64*16	3 wire serial	2.5V	1024	8P/SOIC
18697	93LC46X/SN	MICRO-CHIP	1 K2.5V Microwire Serial EEPROM	128*8or 64*16	3 wire serial	2.5V	1024	8P/SOIC
19749	93LC56B-SN	MICRO-CHIP	2 KMicrowire Compatible Serial EEPROM	128*16	3 wire serial	7V	2048	8P/SOIC
18698	93LC56B/P	MICRO-CHIP	2K 2.5VMicrowire Serial EEPROM	256*8or 128*16	3 wire serial	2.5V	2048	8P/DIP
18699	93LC56N	MICRO-CHIP	2 K 2.5V Microwire Serial EEPROM	256*8or 128*16	3 wire serial	2.5V	2048	8P/DIP
3679	93LC66B/P	MICRO-CHIP	Microchip 3-WireInterface Serial EEPROMs	512*8or 256*16	3 wire serial	2.5V	4096	8P/DIP
18700	93LC66BT/SN	MICRO-CHIP	Microchip 3-WireInterface Serial EEPROMs	512*8or 256*16	3 wire serial	2.5V	4096	8P/SOIC
18701	93LC86/P	MICRO-CHIP	16K 2.5V MicrowireR Serial EEPROM	1024*8or 512*16	3 wire serial	2.5V	8192	8P/DIP
22442	AT17C512-10JC	ATMEL	FPGA ConfigurationEEPROMmemory	512K	2-wire Bus	-0.5-7V	1M-bits	20P/PLCC
22447	AT17LV512-10PC	ATMEL	FPGA ConfigurationEEPROMMemory		2-wire Bus	-0.5-7V	512-Kbit	8P/PDIP
13058	AT17LV65-10PC	ATMEL	FPGA ConfigurationEEPROM Memory	524,288*1	2 wire serial	7V	65K	8P/DIP
24785	AT24C01-10PI.2.7		2-Wire Serial EEPROM	128*8	2-Wire Serial		1 K	DIP/8P
18702	AT24C01A-10SI-2.7	ATMEL	2-Wire Serial EEPROM	128*8	2-Wire Serial	2.7V	1 K	8P/SOIC
1503	AT24C02-10PC-2.7	ATMEL	2-wire Serial EEPROM	256*8	2 wire serial	2.7V	2 K	8P/DIP
18703	AT24C02-10PI-2.7	ATMEL	2-wire Serial EEPROM	256*8	2 wire serial	2.7V	2 K	8P/DIP
18704	AT24C02-10TI-2.7	ATMEL	2-wire Serial EEPROM	256*8	2 wire serial	2.7V	2 K	8P/TSSOP

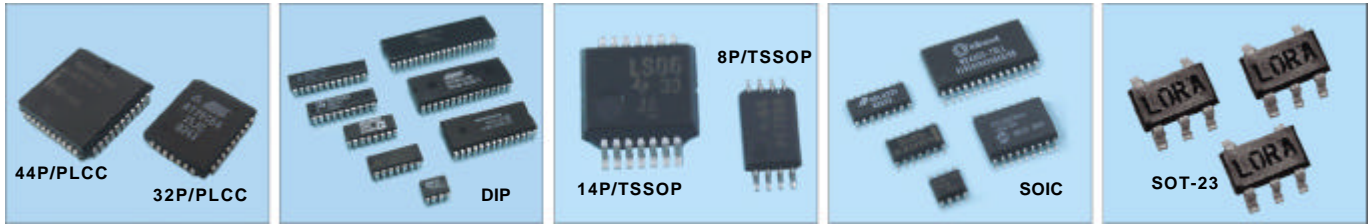


MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	Organisation	BusConfiguration	Volt.(Vcc)	Size(bits)	Pins/Package
18705	AT24C02N-10SI-2.7	ATMEL	2-wire SerialEEPROM	256*8	2-wire serial	2.7V	2K	8P/SOIC
1505	AT24C04-10PC	ATMEL	2-wire Automotive SerialEEPROM	512*8	2-wire serial	5V	4K	8P/DIP
23530	AT24C04-10PI	ATMEL	2-wire SerialEEPROM		2-wire serial	1.8~5.5V		8P/DIP
18707	AT24C04AN-10SC-2.7	ATMEL	2-wire Automotive SerialEEPROM	512*8	2-wire serial	2.7V	4K	8P/SOIC
18711	AT24C04N-10SC-2.7	ATMEL	2-wire Automotive SerialEEPROM	512*8	2-wire serial	2.7V	4K	8P/SOIC
18714	AT24C04N-10SI-2.7	ATMEL	2-wire Automotive SerialEEPROM	512*8	2-wire serial	2.7V	4K	8P/SOIC
1507	AT24C08-10PC	ATMEL	2-wire SerialEEPROM	1K*8	2-wire serial	5V	8K	8P/DIP
17616	AT24C08A-10PI-2.7	ATMEL	2-wire SerialEEPROM	1K*8	2-wire serial	2.7V	8K	8P/DIP
18715	AT24C08AN-10SI-2.7	ATMEL	2-wire SerialEEPROM	1K*8	2-wire serial	2.7V	8K	8P/SOIC
16896	AT24C1024-10PI-2.7	ATMEL	2-wire SerialEEPROM	128K*8	2-wire serial	2.7V	1M	8P/DIP
17149	AT24C128PC	ATMEL	2-wire SerialEEPROMs	16,384*8	2-wire Serial	2.7V	131,072	8P/DIP
19610	AT24C128PI-2.7	ATMEL	2-wire SerialEEPROMs	16,384*8	2-wire Serial	2.7V	131,072	8P/DIP
16499	AT24C128SI-2.7	ATMEL	2-wire SerialEEPROMs	16,384*8	2-wire Serial	2.7V	131,072	8P/SOIC
1509	AT24C16-10PC	ATMEL	2-wire SerialEEPROM	2K*8	2-wire serial	5V	16K	8P/DIP
16884	AT24C16-10PI-2.7	ATMEL	2-wire EEPROM	2K*8	2-wire serial	2.7V	16K	8P/DIP
18717	AT24C16A-10PI-2.7	ATMEL	2-wire SerialEEPROM	2K*8	2-wire serial	5V	16K	8P/DIP
18718	AT24C16AN-10SI-2.7	ATMEL	2-wire SerialEEPROM	2K*8	2-wire serial	5V	16K	8P/SOIC
1508	AT24C16N-10SC-2.7	ATMEL	2.7V 16K(2K*8)EEPROM	2K*8	2-wire serial	2.7V	16K	8P/SOP
18719	AT24C16N-10SI-2.7	ATMEL	2.7V 16K(2K*8)EEPROM	2K*8	2-wire serial	2.7V	16K	8P/TSSOP
18720	AT24C21-10PI-2.5	ATMEL	2-Wire SerialEEPROM	128*8	2-wire serial	2.5V	1K	8P/DIP
22452	AT24C21N-10SC-2.5	ATMEL	2-Wire SerialEEPROM	128*8	2-Wire Serial	2.5~5.5V	1Kbit	8P/SOIC
15982	AT24C256-10PI-2.7	ATMEL	2-wire SerialEEPROM	32K*8	2-wire serial	2.7V	256K	8P/DIP
16503	AT24C256N-SI-2.7	ATMEL	2-wire SerialEEPROMs	32,768*8	2-wire Serial	2.7V	256K	8P/SOIC
1510	AT24C32-10PC	ATMEL	2-Wire SerialEEPROM	4K*8	2-wire serial	5V	32K	8P/DIP
18721	AT24C32N-10SC-2.7	ATMEL	2-Wire SerialEEPROM	4K*8	2-wire serial	2.7V	32K	8P/TSSOP
16985	AT24C512-10PI-2.7	ATMEL	2-wire SerialEEPROM (工業用)	64K*8	2-wire serial	2.7V	512K	8P/DIP
23531	AT24C512N-10SI-2.7	ATMEL	2-wire SerialEEPROM	65,536*8	2-wire Serial	2.7~5.5V	512K	8P/SOIC
15897	AT24C64-10PI-2.7	ATMEL	2-Wire SerialEEPROM (工業用)	8K*8	2-wire serial	2.7V	64K	8P/DIP
18722	AT24C64N-10SC-2.7	ATMEL	2-Wire SerialEEPROM	8192*8	2-wire serial	2.7V	64K	8P/SOIC
23532	AT24C64N-10SI-2.5	ATMEL	2-Wire SerialEEPROM	8192*8	2-wire serial	2.5~5.5V	64K	8P/SOIC
22453	AT25020-10PC	ATMEL	SPI SerialEEPROM	256*8	3-wire serial	2.7~5.5V	2K	8P/PDIP
17310	AT25040-10PI-2.7	ATMEL	SPI SerialEEPROMs	512*8	3-wire serial	5.5V	4K	8P/DIP
22456	AT25040-10SI-2.7	ATMEL	SPI SerialEEPROM	512*8	3-wire serial	2.7~5.5V	4K	8P/SOIC
1514	AT28C16-15PC	ATMEL	16K (2Kx8)ParallelEEPROMs	2K*8		5V	16K	24P/DIP
1490	AT28C16-20JC	ATMEL	PCMCIA Nonvolatile Attribute Memory	2K*8		5V	16K	32P/PLCC
18723	AT28C16-20PC	ATMEL	16K (2Kx8) ParallelEEPROMs	2K*8		5V	16K	24P/DIP
18724	AT28C256-15JC	ATMEL	256K(32K*8)ParallelEEPROMs	32K*8	3-wire serial	5V	256K	32P/PLCC
1491	AT28C256-15PC	ATMEL	AtmelParallelEEPROMs	32K*8	3-wire serial	5V	256K	28P/DIP
18725	AT28C256-15PI	ATMEL	256K (32K*8)ParallelEEPROMs	32K*8	3-wire serial	5V	256K	28P/DIP
1492	AT28C64-15JC	ATMEL	AtmelParallelEEPROMs	8K*8	2-wire serial	5V	64K	32P/PLCC
1515	AT28C64B-15PC	ATMEL	EEPROM with Page Write and Software Data Protection	8K*8	2-wire serial	5V	64K	28P/DIP
18726	AT28C64E-25JC	ATMEL	EEPROM with Page Write and Software Data Protection	8K*8	2-wire serial	5V	64K	32P/PLCC
1522	AT93C46-10PC	ATMEL	3-wire SerialEEPROMs	64*16	3-wire Serial	5V	1K	8P/DIP
1523	AT93C46-10PC-2.7	ATMEL	3-wire SerialEEPROMs	64*16	3-wire Serial	2.7V	1K	8P/DIP
18727	AT93C46-10PI-2.7	ATMEL	3-wire SerialEEPROMs	128*8or64*16	3-wire Serial	5V	1K	8P/DIP
18728	AT93C46-10SC	ATMEL	3-wire SerialEEPROMs	128*8or64*16	3-wire Serial	5V	1K	8P/SOIC
1524	AT93C46-10SC-1.8	ATMEL	3-wire SerialEEPROMs	64*16	3-wire Serial	1.8V	1K	8P/SOIC
18729	AT93C46-10SC-2.7	ATMEL	3-wire SerialEEPROMs	128*8or64*16	3-wire Serial	5V	1K	8P/TSSOP
1525	AT93C46-10SI-2.7	ATMEL	EEPROM 8P-SOP(I)	64*16	3-wire Serial	2.7V	1K	8P/SOP
18730	AT93C46A-10SI-2.5	ATMEL	3-wire SerialEEPROMs	128*8or64*16	3-wire Serial	5V	1K	8P/SOIC
18731	AT93C46R-10SC	ATMEL	3-wire SerialEEPROMs	128*8or64*16	3-wire Serial	5V	1K	8P/SOIC
18732	AT93C46R-10SC-2.7	ATMEL	3-wire SerialEEPROMs	128*8or64*16	3-wire Serial	5V	1K	8P/SOIC
17170	AT93C56-10PC	ATMEL	3-wire SerialEEPROMs	128*16	3-wire Serial	5.5V	2K	8P/DIP
1499	AT93C56-10PC-2.7	ATMEL	MICROWIRE Serial AccessEEPROM	128*16	3-wire Serial	2.7V	2K	8P/DIP
18733	AT93C56-10SC	ATMEL	3-wire SerialEEPROMs	256*8or128*16	3-wire Serial	5V	2K	8P/SOIC
18734	AT93C66-10PC	ATMEL	3-wire SerialEEPROMs	512*8or256*16	3-wire Serial	2.5V	4K	8P/DIP
1500	AT93C66-10PC-2.7	ATMEL	3-wire SerialEEPROMs	256*16	3-wire Serial	2.7V	4K	8P/DIP
1527	AT93C66-10PI-2.7	ATMEL	EEPROM	256*16	3-wire Serial	2.7V	4K	8P/DIP
18735	AT93C66-10SC	ATMEL	3-wire SerialEEPROMs	512*8or256*16	3-wire Serial	2.5V	4K	8P/SOIC
1528	AT93C66-10SC-2.5	ATMEL	3-wire SerialEEPROMs	256*16	3-wire Serial	2.5V	4K	8P/SOP
18736	AT93C66-10SI-2.7	ATMEL	3-wire SerialEEPROMs	512*8or256*16	3-wire Serial	2.7V	4K	8P/SOIC
14147	AT93C86-10SC/2.7	ATMEL	3-wire SerialEEPROM	2048*8or1024*16	3-wire serial	2.7V	16K	8P/SOIC
23543	AT93C86-10SI-2.7	ATMEL	3-wire SerialEEPROM	2048*8or1024*16	3-wire Serial	2.7~5.5V	16K	8P/SOIC
18737	CAT24WC02J	CATALYST	2K BitSerialEEPROM	512*8		1.8V	2K	8P/SOIC
22514	CAT93C46P	CATALYST	Microwire SerialEEPROM			1.8~6.0V	1K*8or16	8P/PDIP



MEMORY IC



PartNo.	ProductNo.	Manuf.	Description	Organisation	Bus Configuration	Volt.(Vcc)	Size(bits)	Pins/Package
22515	CAT93C56S-2.7	CATALYST	2K-bit Serial EEPROM memory devices			1.8~6.0V	2K*8or16	8P/SOIC
18738	CAT93C66P	CATALYST	4K Bit Microwire Serial EEPROM			1.8V	4 K	8P/DIP
18739	CAT93C66S	CATALYST	4 K Bit Microwire Serial EEPROM			1.8V	4 K	8P/SOIC
22516	CAT93C86S-TE13	CATALYST	Microwire Serial EEPROM			1.8~6.0V	16K*8or16	8P/SOIC
23550	FM27C040Q120	Fairchild	High Performance CMOS EPROM	512K*8		-0.6~7V		32P/DIP
18755	HT24LC02	HOLTEK	2K 2-Wire CMOS Serial EEPROM	256*8	2 wire serial	2.4~5.5V	2 K	8P/DIP
27929	HT93LC46-B	HOLTEK	EEPROM	64*16	Serial/O	3~5V	1 K	8P/SOP
18756	KM93C46GD	SAMSUNG	1024-bits serial electrically erasable PROM			5V	1024	8P/SOP
22687	M24C01-WDW6T	ST(SGS)	Bus EEPROM	128*8	2 wire serial	2.5~5.5V	1 K	8P/TSSOP
22698	M28C64-20K6	ST(SGS)	Parallel EEPROM with Software Data Protection	8K*8		5V	64K	32P/PLCC
22699	M28C64C-200K1	ST(SGS)	Parallel EEPROM	8K*8		5V	64K	32P/PLCC
1538	M9306B	ST(SGS)	EEPROM(同NM9306N) SGS-Thomson	16*16	Serial/O	5V	256K	8P/DIP
22703	M93C46-MN6	ST(SGS)	Serial Microwire Bus EEPROM	1K*8or16		4.5~5.5V	1 K	8P/SOP
18757	NM24C08LM8X	NEC	2-Wire Bus Interface Serial EEPROM		2 wire serial	2.4~5.5V	8 K	8P/SOIC
22774	NM93C06M8	N.S	Serial EEPROM			4.5~5.5V	256Bits	8P/SOP
18759	S93CC46BD-J8T1	SII	1K-bit serial EEPROM	64*16			1 K	8P/SOP
23603	SST29EE020-120-4C-NH	SST	Page-Mode EEPROM	256K*8		5.0V	2 M	32P/PLCC
22840	ST24LW21FB6	ST(SGS)	Dual Mode Serial EEPROM For Vesa Plug&Play	128*8	2 wire serial	3.6~5.5V	1Mbit	8P/DIP
23610	TC58V64BFT	TOSHIBA	CMOS NAND EEPROM	8M*8 BIT		2.7~3.6V	64M	44P/TSOP
23546	X24645	XICOR	Advanced 2-Wire Serial EEPROM with Block Lock Protection	8*8192	2-wire serial	2.7~5.5V	64Kbit	8P-SOIC
23151	X24C02S8-3T	XICOR	Serial EEPROM	256*8 Bit	2 wire serial	2.7~5.5V	2 M	8P/SOIC
19109	X24C44P	XICOR	CMOS Serial NOVRAM	16*16(256B)	Serial Port Compatible	5V 10%	256BIT	8P-DIP
20244	X24C44S	XICOR	CMOS Serial NOVRAM	16*16(256B)	Serial Port Compatible	5V 10%	256BIT	8P-SOIC
18794	X2816CP-20	XICOR	5 Volt, Byte Alterable EEPROM	2K*8		5V	16K	24P/DIP
18809	X28C16J	EXEL	PCMCIA Nonvolatile Attribute Memory	2K*8		5V	16K	32P/PLCC
13196	X28C64P-20	XICOR	64K (8K x 8bit) 5 volt, byte alterable EEPROM	8K*8	3 wire serial	5V	64K	28P/DIP
18807	XL93LC56JR		2K 2.5V Microwire Serial EEPROM	256*8 or 128*16	3 wire serial	2.5V	2048	SMD
1544	XL93LC66F	EXEL	EEPROM	256*16	3 wire serial	5V	4 K	8P/SOP
18808	XL93LC66Y	EXEL	Microchip 3-Wire Interface Serial EEPROMs	512*8 or 256*16	3 wire serial	2.5V	4096	8P/SOIC

靜態式記憶體 SRAM

詳細產品規格--請點擊 www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	Access time	Pins/Package
19030	BS62LV1024SC-70	BSI	Very Low Power/voltage CMOS SRAM	1M	128K*8	70ns	32P/SOP
19032	BS62LV2001SC-70	BSI	Very Low Power/Voltage CMOS SRAM		256K*8	70ns	32P/SOP
19034	BS62LV256PC-70	BSI	Very Low Power/Voltage CMOS SRAM		32K*8	70ns	28P/PDIP
19035	BS62LV256SC-70	BSI	Very Low Power/Voltage CMOS SRAM		32K*8	70ns	28P/SOP
14092	BS62LV256TC-70	BSI	Very Low Power/voltage CMOS SRAM	256K	32K*8	70ns	28P/TSOP
1581	CXK581000AM-70SL	SONY	131072-word x 8-bit High Speed CMOS Static RAM	1M	131072*8	70ns	32P/SOP
19036	CXK581000ATM-10LL	SONY	256K-SRAM	256K	32768*8	100ns	32P/TSOP
19037	CXK581000ATM-10SL	SONY	256K-SRAM SUPER LOW POWER	256K	32768*8	100ns	32P/TSOP
19038	CXK581000ATM-70LL	SONY	256K-SRAM SUPER LOW POWER	256K	32768*8	70ns	32P/TSOP
19039	CXK581001M-70L	SONY	SRAM	1M		70ns	SMD
1583	CXK5816M-15L	SONY	16K-SRAM	16K	2048*8	150ns	24P/SOP
19040	CXK5816MA-15L	SONY	SRAM	16K	2K*8	150ns	24P-SMD
1589	CXK58257ASP-120ns	SONY	256K-SRAM	256K	32768*8	120ns	28P/DIP-300mil
19041	CXK58257ATM-10L	SONY	256K-SRAM	256K	32768*8	100ns	28P/TSOP
19042	CXK58257ATM-10LL	SONY	256K-SRAM	256K	32768*8	100ns	28P/TSOP
19043	CXK58257ATM-10LLX	SONY	256K-SRAM	256K	32768*8	100ns	28P/TSOP
19044	CXK58257ATM-10LX	SONY	256K-SRAM	256K	32768*8	100ns	28P/TSOP
1586	CXK58257ATM-12LL	SONY	256K-SRAM	256K	32768*8	120ns	28P/SOIC
19045	CXK58257BM-10LL	SONY	SRAM	256K	32768*8	100ns	SMD
23544	CXK58257CM-70LL	SONY	High Speed CMOS Static RAM	32768	word*8bit	70ns	28P/SOIC
19046	CXK584000YM-70LL	SONY	SRAM	4M			TSOP
1590	CXK5864CP-10LL	SONY	64K-SRAM	64K	8192*8	100ns	24P/DIP
19047	CXK5T81000ATM-10LLX	SONY	SRAM			100ns	TSOP



MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	Access time	Pins/Package
19048	CXK5T8257BM-12LLX	SONY	SRAM			120ns	SMD
19049	CXK5V81000ATM-10LLX	SONY	SRAM			100ns	TSOP
19050	CXK5V8257BM-70LL	SONY	SRAM			70ns	SMD
19051	CY62128BLL-70SC	Cypress	128K*8 Static RAM		128K*8	70ns	32P/SOIC
23547	CY62128L-70SC	Cypress	Static RAM		128K*8	70ns	32P/SOIC
19052	CY62256LL-70SNC	Cypress	32K*8 Static RAM		32K*8	70ns	28P/SOIC
17362	CY7C128A-35DMB	Cypress	Static RAM	16K	2K*8	35ns	24P/DIP
22331	CY7C136-55JC	Cypress	Dual-Port Static RAM	16K	2K*8	55ns	52P/PLCC
23262	CY7C150-35DMB	Cypress	1K*4 Static RAM		1K*4	35ns	24P/DIP
17363	CY7C185A-35DMB	Cypress	Static RAM	64K	8K*8	35ns	28P/DIP
22574	CY7C199-15VCT	Cypress	32K*8 Static RAM		32K*8	15ns	28P/SOJ
23261	CY7C245A-35DMB	Cypress	Reprogrammable Registered PROM	16K	2K*8	35ns	24P/DIP
23648	CY7C245A-35WC	Cypress	Reprogrammable Registered PROM	16K	2K*8	35ns	24P/Windowed DIP
17364	CY7C263-45DMB	Cypress	8K*8 Power-Switched and Reprogrammable PROM	64K	8K*8	45ns	24P/DIP
16404	D431000ACZ-70L	NEC	1M-BIT CMOS STATIC RAM	1M	128*8bit	70ns	32P/DIP
23561	EM638165-6	Etron	SRAM	4K	4Meg*16	60ns	TSOP/54P
19053	GM76C256CLLFW-55	HYNIX	SRAM			55ns	SMD
19055	GM76C8128CLLFW-85	HYNIX	SRAM	1M		85ns	SMD
19054	GM76C8128CLLFW-70	HYNIX	SRAM	1M		70ns	SMD
19056	GM76FC18ALLFW-70	HYNIX	SRAM	1M			SMD
19025	GM76V8128CLFW-70	HYNIX	SRAM	1M		70ns	SMD
19026	GM76V8128CLLFW-70	HYNIX	SRAM	1M			SMD
1597	HM6116LM-70	HMC	SRAM	16K	2K*8	70ns	24P/SOP
19028	HM6116P-70L	HITACHI					
19057	HM6264LM-70	HMC	SRAM	8K*8	8192*8	70ns	SMD
17171	HM6264LP-70	HMC	SRAM	8K*8	8192*8	70ns	28P/DIP
19058	HM6264WM-70L	HMC	SRAM	8K*8	8192*8	70ns	28P/SOP
19059	HM628128DLFP-55SL	HITACHI	1 M SRAM(128-kword*8-bit)	1M	128K*8	55ns	32P/SOP
19060	HM628512CLFP-5SL	HITACHI					32P/SOIC
4488	HM62V8128BLT-12	HITACHI	SRAM	1M	128K*8	120ns	32P/TSOP
19061	HMT65756N-5	MHS					
19062	HY628100BLLG-70		128K*8 bit 5.0V Low Power CMOS slow SRAM		128K*8	70ns	32P/SOP
23263	IDT6116SA45TDB	IDT	CMOS Static RAM	16K	2K*8bit	45ns	24P/DIP
23646	IS61C1024-12J	ISSI	HIGH-SPEED CMOS STATIC RAM	131072Words	128K*8	12ns	32P-SOJ
23551	IS61C1024-15T	ISSI	HIGH-SPEED CMOS STATIC RAM	131072Words	128K*8	15ns	32P/TSOP
23552	IS61C256AH-15J	ISSI	HIGH-SPEED CMOS STATIC RAM	256K	32K*8	15ns	28P/SOIC
22626	IS61C256AH-20T	ISSI	HIGH-SPEED CMOS STATIC RAM		32K*8	20ns	28P/TSOP
22627	IS61C512-15N	ISSI	HIGH-SPEED CMOS STATIC RAM		64K*8	15,20,25,35ns	32P/DIP
23553	IS61C64AH-20N	ISSI	HIGH-SPEED CMOS STATIC RAM	64K	8K*8	20ns	28P/SOIC
22631	IS61S6432-5PQ	ISSI	SYNCHRONOUS PIPELINE STATIC RAM		64K*32	4ns	100P/PQFP
19063	IS62C1024-70Q	ISSI	128K*8 HIGH-SPEED CMOS STATIC RAM	1M	128K*8	70ns	32P/TSOP
22633	IS62LV1024LL-55H	ISSI	LOW POWER and LOW Vcc CMOS STATIC RAM		128K*8	45,55,70ns	32P/TSOP
22634	IS62LV1024LL-70T	ISSI	LOW POWER and LOW Vcc CMOS STATIC RAM		128K*8	45,55,70ns	32P/TSOP
22635	IS63LV1024-12J	ISSI	HIGH-SPEED CMOS STATIC RAM		128K*8	10,12,15ns	32P/SOJ
27819	K4S561632E-TL75	SAMSUNG	256Mb E-die SDRAM Specification	256M	16M*16		54P/TSOP
19064	K6T1008C2C-DB55	SAMSUNG	128K*8 bit Low Power CMOS Static RAM	1M	128K*8	55ns	32P/DIP
19065	K6T1008C2C-GB55	SAMSUNG	128K*8 bit Low Power CMOS Static RAM	1M	128K*8	55ns	32P/SOP
19067	K6T1008C2E-GB70	SAMSUNG	128K*8 bit Low Power CMOS Static RAM	1M	128K*8	70ns	32P/SOP
23554	K6T1008C2E-GF70	SAMSUNG	Low Power CMOS Static RAM		128K*8bit	70ns	32P/SOIC
23555	K6T1008C2E-TB70	SAMSUNG	Low Power CMOS Static RAM		128K*8bit	70ns	32P/TSOP
19068	K6T4008C1B-GB55	SAMSUNG	512K88 bit Low Power CMOS Static RAM	4M	512K*8	55ns	32P/SOP
23556	K6T4008C1B-GP70	SAMSUNG	Low Power CMOS Static RAM		512K*8bit	70ns	32P/SOIC
19069	K6T4008C1C-GB55	SAMSUNG	512K*8 bit Low Power CMOS Static RAM	4M	512K*8	55ns	32P/SOP
23564	K6X1008C2D-DF70	SAMSUNG	Low Power full CMOS Static RAM		128K*8	70ns	32P/DIP
23565	K6X1008C2D-GB70	SAMSUNG	Low Power full CMOS Static RAM		128K*8	70ns	32P/SOIC
23566	K6X1008C2D-TB70	SAMSUNG	Low Power full CMOS Static RAM		128K*8	70ns	32P/TSOP
26222	K6X4008C1F-DF55	SAMSUNG	512K*8 bit Low Power CMOS Static RAM	4M	512K*8	70ns	32P/DIP
23567	K6X4008C1F-GB55T	SAMSUNG	Low Power full CMOS Static RAM		512K*8bit	55ns	32P/SOIC
25935	K6X4008C1F-GB70	SAMSUNG	512K*8 bit Low Power CMOS Static RAM	4M	512K*8	70ns	32P/DIP
19070	KM62256ALG-10L	SAMSUNG	SRAM			100ns	SMD
19071	KM681000BLG-7L	SAMSUNG	128K*8 bit Low Power CMOS Static RAM	1M	128K*8	32P/SOP	SMD
19066	L6T1008C2E-GB55	SAMSUNG	128K*8 bit Low Power CMOS Static RAM	1M	128K*8	55ns	32P/SOP
19072	LC3564B-70	SANYO	SRAM with OECE1 and CE2 Control Pins	64K	8192*8	70ns	28P/DIP
19073	LC361000AMLL-70	SANYO	1 MEG (131072 words x 8bits) SRAM	1M	131072*8	70ns	32P/SOP
1604	LH5164L-10	SHARP	SRAM	64K	8K*8	100ns	28P/DIP



MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	Access time	Pins/Package
19074	LH52B256D-10PLL	MOSEL-VIT.	SRAM			100ns	DIP
19075	LH5P8128N-80	SHARP	SRAM	1M		80ns	32P/SOP
27935	LP621024DM-70LL		SRAM		128K*8		SOP-32P
19076	LST62832I-70LL	LINK-SMART	SRAM			70ns	28P/DIP
22759	M5M51008AVP-10VLL	MITSUBISHI	SRAM	1M	128K*8	70nS	TSOP
19078	M5M51008BFP-10VLL	MITSUBISHI	SRAM,3.3V	1M			TSOP
19077	M5M51008BP-70LL	MITSUBISHI	SRAM	1M		70ns	32P/SOIC
19079	M5M51008CFP-70H	MITSUBISHI	SRAM	1M		70ns	32P/SOIC
19080	M5M51008CFP-70HI	MITSUBISHI	SRAM	1M			32P/SOP
19081	M5M51008CP-70H	MITSUBISHI	SRAM	1M			32P/DIP
19082	M5M51008DVP-70H	MITSUBISHI	SRAM	1M		70ns	TSOP
19083	M5M51008FP-70L	MITSUBISHI	SRAM			70ns	32P/SOIC
19084	M5M5255DFP-70LL	MITSUBISHI	SRAM			70ns	28P/SOIC
1608	M5M5256CP-70LL	MITSUBISHI	SRAM	256K	32K*8	70ns	28P/DIP
19085	M5M5256DFP-10L	MITSUBISHI	SRAM			100ns	28P/SOIC
19090	M5M5256DFP-70LL	MITSUBISHI	SRAM			70ns	28P/SOIC
19091	M5M5256DVP-45LL	MITSUBISHI	SRAM			45ns	28P/TSOP
19092	MB84256C-70LLPFTN	FUJITSU	SRAM			70ns	TSOP
19097	MS6264CL-15FC	FUJITSU	SRAM			150ns	SOP
19098	MSM51257ALL-85RS	OKI	SRAM			85ns	DIP
19338	MSM6242BRS	OKI	Direct Bus Connected CMOS Real Time Clock/calendar				18P/DIP
23368	MT48LC4M16A2-75F		SRAM	4K	4Meg*16	5.4ns	TSOP/54P
19151	PALCE16V8H-15JC/4	AMD	FLASH Erasable,Reprogrammable CMOS PAL Device	15	0~75C	+4.75~+5.25	20P/PLCC
19152	PALCE16V8H-15JC/4	LATTICE	FLASH Erasable,Reprogrammable CMOS PAL Device	15	0~75C	+4.75~+5.25	20P/PLCC
19153	PALCE16V8H-15PC/4	AMD	FLASH Erasable,Reprogrammable CMOS PAL Device	15	0~75C	+4.75~+5.25	20P/DIP
19154	PALCE16V8H-25JC/4	AMD	FLASH Erasable,Reprogrammable CMOS PAL Device	25	0~75C	+4.75~+5.25	20P/PLCC
19156	PALCE16V8H-7JC/5	AMD	FLASH Erasable,Reprogrammable CMOS PAL Device	7	0~75C	+4.75~+5.25	20P/PLCC
19157	PALCE16V8Q-15JC/4	AMD	FLASH Erasable,Reprogrammable CMOS PAL Device	15	0~75C	+4.75~+5.25	20P/PLCC
19099	S65728AM	MHS	SRAM			55ns	SMD
19101	TC551001BFL-70	TOSHIBA	SRAM			70ns	SMD
19102	TC55257DFL-70L	TOSHIBA	SRAM			70ns	SMD
19086	TMM2016BP-12		SRAM			120ns	DIP
19087	UM6116M-3L	UMC	SRAM			90ns	SMD
1559	UPD431000ACZ-70LL	NEC	1M-SRAM 32P-DIP	1M	131072*8Bits	70ns	32P/DIP
19088	UPD431000AGW-70LL	NEC	1M-BITCMOS STATICRAM	1M	128K*8	70ns	32P/SOP
19089	UPD431000AGZ-70LL-KJH	NEC	1M-SRAM	1M	131072*8Bits	70ns	32P/TSOP
1569	UPD43256BCZ-70LL	NEC	256K-BITCMOS STATICRAM 32K-WORDBY 8-BIT	256K	32768*8	70ns	28P/DIP
19103	UT621024SC-70L	UTRON	128K*8 BITLOWPOWER CMOS SRAM	1M	128K*8	70ns	32P/SOP
23622	UT62256CPC-70LL	UTRON	LOW POWERCMOS SRAM		32K*8	70ns	28P/DIP
23623	UT62256CSC-70LL	UTRON	LOWPOWER CMOS SRAM	256K	32K*8	70ns	28P/SOIC
22192	UT62256SC-70LL	UTC	32 K*8 Bit lowpowerCMOS SRAM	256K	32768*8	70ns	SOP-28300mil
23145	V62C518256LL-70F	MOSEL-VIT.	STATICRAM	256K	32K*8	70ns	28P/SOIC
19104	V62C51864L-35P	MOSEL-VIT.	SRAM			35ns	28P/DIP
19105	V62C51864L-70P	MOSEL-VIT.	SRAM			70ns	28P/DIP
27907	W24257AJ-12		靜態式記憶體	256K	32K*8	12nS	8P/SOJ
23147	W24257AJ-15	WINBOND	HIGHSPEED CMOS STATICRAM	256K	32K*8	15nS	8P/SOJ
23148	W24257AK-15	WINBOND	HIGHSPEED CMOS STATICRAM	256K	32K*8	15nS	28P/DIP
19107	W24257S-100L	WINBOND	32K*8 CMOS STATIC RAM		32K*8	100ns	28P/SOP
19106	W24257S-70L	WINBOND	32K*8 CMOS STATICRAM		32K*8	70ns	28P/SOP
14258	W24257S-70LL	WINBOND	32K*8 CMOS STATICRAM	256K	32768*8Bits	70ns	28/SOP
5379	W24258-70LL	WINBOND	32*8 normal speed, very low powerCMOSstaticRAM	256K	32768*8Bits	70ns	28P/DIP
19108	W24258S-70LE	WINBOND	32K*8 CMOS S TATICRAM		32K*8	70ns	28P/SOP
15752	W24258S-70LL	WINBOND	32*8 normal speed, very low powerCMOSstaticRAM	32768*8Bits	32K*8	70ns	28P/SOP
1548	W2465S-70LL	WINBOND	8K*8 CMOS STATIC RAM	64K	8K*8	70ns	28P/SOP
15500	W24L11Q-70LE	WINBOND	128K*8CMOS STATICRAM	128K*8	131072*8	70ns	32P/TSOP
23149	W24L257AJ-15	WINBOND	HIGH-SPEEDCMOS STATICRAM	256K	32K*8	15nS	28P/SOJ
19100	TC551001AFL-10LL	TOSHIBA	SRAM	1M		100ns	SMD
15129	TMS9914ANL(新)	T.I.	SRAM				40P/DIP

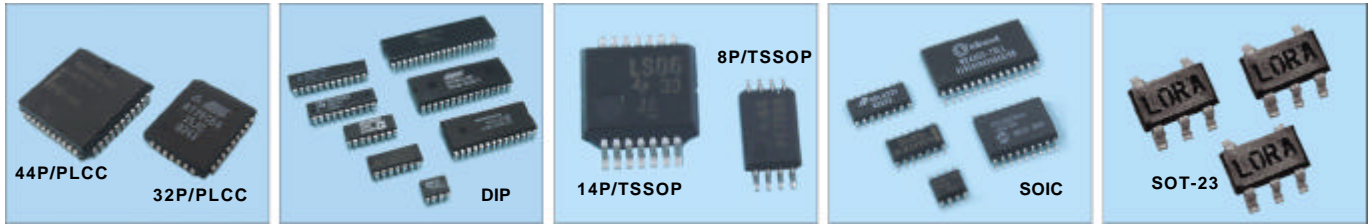
Nonvolatile SRAM

詳細產品規格--請點擊www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	Size	Access time	Pins/Package
16257	DS1210	DALLAS	NonvolatileController Chip		20ns	8P/DIP
4845	DS1220Y-150	DALLAS	NonvolatileSRAM2K*8	16K	150ns	24P/DIP



MEMORY IC



PartNo.	ProductNo.	Manuf.	Description	Size	Accesstime	Pins/Package
4481	DS1225Y-150	DALLAS	64K nonvol. SRAM10% pwr4.37VWP	64K	150ns	28P/DIP
4479	DS1230Y-100	DALLAS	256K nonvol. SRAM10% pwr, 4.37V WP	256K	100ns	28P/DIP
17126	DS1245Y-70	DALLAS	Nonvolatile SRAM(1024 Nonvolatile sram)	1024K	70ns	32P/DIP
16564	DS1249Y-70	DALLAS	Nonvolatile SRAM(2048 Nonvolatile sram)	2048K	70ns	32P/DIP
19320	DS1302	DALLAS	Trickle Charge Timekeeping Chip			8P/DIP
19321	DS1302S	DALLAS	Trickle Charge Timekeeping Chip			8P/SOIC
22290	X24C44	XICOR	Serial NonvolatileStatic RAM	16*16 Bit		8P/SOIC

先進先出型-記憶體 FIFOProducts

詳細產品規格--請點擊www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	Organisation	Accesstime	Pins/Package
20112	CY7C429-20PC	Cypress	Asynchronous FIFO(2Kx 9asynchronous FIFO, 30 ns)	2K*9	20ns	28P/DIP
16449	CY7C429-30PC	Cypress	Asynchronous FIFO(2K x 9 asynchronous FIFO,30 ns)	2K*9	40ns	28P/DIP
17480	IDT7210L45J	IDT	Multipliers and Dividers	16*16 Bit	45ns	68P-PLCC
21983	IDT72245LB10PF		CMOS SyncFIFO	4096*18Bit	10ns	TQFP 64
13205	SN74ACT72241L50RJ	T.I.	synchronousFIFO	4K*9	15ns	32P/PLCC

快閃式記憶體 快閃式記憶體 FLASHMEMORY

詳細產品規格--請點擊www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	Accesstime	SupplyVolt.	Pins/Package
16898	A290011T-70	AMIC	Boot Sector Flash Memory		128K*8	70ns	5V	32P/DIP
1493	AM28F010-150PC	AMD	1 megabit CMOS 12.0 volt, bulk erase flash memory	1M	128K*8	150ns	5V	32P/DIP
10086	AM28F010A-120JC	AMD	1 megabit CMOS 12.0 volt, bulk erase flash memory with embedded algorithms	1M	128K*8	120ns	12V	32P/PLCC
18879	AM28F010A-90FC	AMD	1 megabit CMOS 12.0 volt, bulk erase flash memory with embedded algorithms	1M	128K*8	90ns	12V	32P/TSOP
18880	AM29DL323CB-90EI	AMD						
18881	AM29F002BB-55EC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	2M	262144*8	55ns	5V	32P/TSOP
18882	AM29F002BT-120JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	2M	262144*8	120ns	5V	32P/PLCC
18883	AM29F002BT-90JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	2M	262144*8	90ns	5V	32P/PLCC
7833	AM29F002NBT-55JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	2M	262144*8	55ns	5V	32P/PLCC
18884	AM29F002NBT-90JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	2M	262144*8	90ns	5V	32P/PLCC
18885	AM29F002NT-90JC	AMD	2 megabit CMOS 5.0 volt-only boot sector flash memory	2M	262144*8	55ns	5V	32P/PLCC
1497	AM29F010-120PC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	1M	128K*8	120ns	5V	32P/DIP
3693	AM29F010-90PC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	1M	128K*8	90ns	5V	32P/DIP
18886	AM29F010A-70JI	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	1M	128K*8	70ns	5V	32P/PLCC
18887	AM29F010B-120JC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	1M	128K*8	120ns	5V	32P/PLCC
18900	AM29F010B-55JC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	1M	128K*8	55ns	5V	32P/PLCC
18901	AM29F010B-70JC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	1M	128K*8	70ns	5V	32P/PLCC
18902	AM29F010B-90JC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	1M	128K*8	90ns	5V	32P/PLCC
23518	AM29F016B-120EC	AMD	Sector Erase Flash Memory	16M	2,097,152*8Bit	70ns	5V	48P/TSOP
18903	AM29F016D-90EC	AMD	1 megabit CMOS 5.0 volt-only, uniform sector flash memory	16M	128K*8	90ns	5V	32P/TSOP
18904	AM29F040B-120EC	AMD	4 megabit CMOS 5.0 volt-only, uniform sector flash memory	4M	512K*8	120ns	5V	32P/TSOP
1501	AM29F040B-120PC	AMD	4 megabit CMOS 5.0 volt-only, uniform sector flash memory	4M	512K*8	120ns	5V	32P/DIP
23519	AM29F040B-70JC	AMD	Sector Erase Flash Memory	4M	524,288*8Bit	55ns	5V	32P/PLCC
23520	AM29F040B-90JC	AMD	Sector Erase Flash Memory	4M	524,288*8Bit	55ns	5V	32P/PLCC
1502	AM29F040B-90JI	AMD	4 megabit CMOS 5.0 volt-only, uniform sector flash memory	4M	512K*8	90ns	5V	32P/PLCC
18905	AM29F200B-120EC	AMD	2 Megabit CMOS 5.0 Volt-only, Boot Sector Flash Memory	2M	256*8	120ns	5V	48P/TSOP
18906	AM29F400AT-90EC	AMD	4 Megabit CMOS 5.0 Volt-only, Sector Erase Flash Memory	4M	524,288*8	90ns	5V	48P/TSOP
18907	AM29F400BB-120SC	AMD	4 Megabit CMOS 5.0 Volt-only Boot Sector Flash Memory	4M	512K*8	120ns	5V	48P/TSOP
18908	AM29F400BB-90EC	ATMEL	4 Megabit CMOS 5.0 Volt-only Boot Sector Flash Memory	8M	512K*8	90ns	5V	48P/TSOP
17486	AM29F800BT-70EC	AMD	CMOS 5.0 Volt-only, Boot Sector Flash Memory	1M	512K*16	70ns	5V	48P/TSOP
18913	AM29LV001BB-55EC	AMD	1 Megabit CMOS 3.0 Volt-only Boot Sector Flash Memory	1M	128K*8	55ns	5V	32P/TSOP
23522	AM29LV010B-90JC	AMD	Uniform Sector Flash Memory	1M	128K*8Bit	55ns	2.7~3.6V	32P/PLCC
3692	AM29LV040B-120JI	AMD	4 megabit CMOS 3.0 volt-only uniform 32-pin flash memory	4M	512K*8	120ns	3.3V	32P/PLCC
23523	AM29LV040B-70EC	AMD	Uniform Sector Flash Memory	4M	512K*8Bit	70ns	2.7~3.6V	32P/TSOP



MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	AccessTime	SupplyVolt.	Pins/Package
23524	AM29LV040B-90EC	AMD	Uniform SectorFlash Memory	4 M	512K*8Bit	90ns	2.7~3.6V	32P/TSOP
23525	AM29LV081B-90EC	AMD	Uniform SectorFlash Memory	8 M	1M*8Bit	70ns	3.0V	40P/TSOP
28028	AM29LV160DB-90EC	AMD	16 MegabitCMOS 3.0 Volt-only BootSector Flash Memory	16MG	2M*8bi/1M*16Bit	90ns	2.7*3.6V	48P/TSOP
23650	AM29LV160DT-70EC	AMD	BootSector Flash Memory	16M	2M*8Bit/1M*16Bit	70ns	3.0V	48P/TSOP
23526	AM29LV160DT-90EC	AMD	BootSector Flash Memory	16M	2M*8Bit/1M*16Bit	90ns	3.0V	48P/TSOP
18914	AM29LV200BT-90SC	AMD	2 Megabit CMOS 3.0 Volt-only Boot Sector Flash Memory	2 M	256K*8/128k*16	90ns	5V	48P/TSOP
23527	AM29LV320DB-120EI	AMD	BootSectorFlash Memory	32M	4M*8Bit/2M*16Bit	90ns	3.0V	48P/TSOP
23528	AM29LV800BB-70EC	AMD	BootSectorFlash Memory	8 M	M*8Bit/512K*16Bit	70ns	3.0V	48P/TSOP
18917	AM29LV800BB-90EC	AMD	8 MegabitCMOS 3.0 Volt-only BootSectorFlash Memory	8 M	512*16	90ns	5V	48P/TSOP
23529	AM29LV800BT-120EI	AMD	BootSectorFlash Memory	8 M	1M*8Bit/512K*16Bit	70ns	3.0V	48P/TSOP
18919	AS29F010-15LC	Alliance	5V128K*8 CMOS Flash EEPROM		128K*8	150ns	5V	32P/PLCC
18920	AS29F040-120LC	Alliance	5V 512K*8 CMOS Flash EEPROM		512K*8	90ns	5V	32P/PLCC
18923	AT29C010A-12JC	ATMEL	1-megabit(128K x8) 5-volt Only FlashMemory	1 M	128K*8	120ns	5V	32P/PLCC
18925	AT29C010A-12TI	ATMEL	1-megabit (128K x 8) 5-volt Only FlashMemory	1 M	128K*8	120ns	5V	32P/TSOP
18926	AT29C010A-15JC	ATMEL	1-megabit(128K x 8) 5-volt OnlyFlash Memory	1 M	128K*8	150ns	5V	32P/PLCC
16609	AT29C010A-15PC	ATMEL	1-megabit (128Kx8) 5-volt OnoyFlashMemory	1 M	128K*8	150ns	5V	32P/DIP
23536	AT29C010A-70JC	ATMEL	Flash Memory	1 M	128K*8	70ns	5V	32P/PLCC
18927	AT29C010A-70TC	ATMEL	1-megabit(128K x 8) 5-volt OnlyFlash Memory	1 M	128K*8	70ns	5V	32P/TSOP
1518	AT29C010A-90JI	ATMEL	1 Megabit (128K x 8)5-volt onlyCMOS flashmemory	1 M	128K*8	90ns	5V	32P/PLCC
18928	AT29C010A-90TI	ATMEL	1-megabit(128K x8) 5-volt Only FlashMemory	1 M	128K*8	90ns	5V	32P/TSOP
16610	AT29C020-12PC	ATMEL	2-megabit(256Kx8) 5-volt OnlyFlash Memory	2 M	256K*8	120ns	5V	32P/PLCC
1496	AT29C020-90JI	ATMEL	2-Megabit(256K x 8) 5-volt onlyCMOS flash memory	2 M	256K*8	90ns	5V	32P/PLCC
22461	AT29C040A-12TC	ATMEL	4-megabit5-volt Only 256-byte SectorFlash Memory	4 M	512K*8	-120ns	5V	32P/TSOP
18929	AT29C040A-12TI	ATMEL	4-megabit 5-volt Only256-byte SectorFlashMemory	4 M	512K*8	120ns	5V	32P/TSOP
8809	AT29C256-12JI	ATMEL	256(32x8) 5-volt only CMOS flashmemory	256K	32K*8	120ns	5V	32P/PLCC
18933	AT29LV020-20TI	ATMEL	2-Megabit (256K x 8)3-volt OnlyFlashMemory	2 M	256K*8	200ns	3V	32P/TSOP
8096	AT29LV512-15JC	ATMEL	512K (64Kx8)3-volt OnlyFlash Memory	512K	64K*8	150ns	3.3V	32P/PLCC
18930	AT45DB011B-SC	ATMEL	1-megabit 2.7-volt Only DataFlash	1 M			3.3V	8P/SOIC
23537	AT45DB011B-XC	ATMEL	DataFlash	1 M			2.7V	14P/TSSOP
22468	AT45DB041A-RC	ATMEL	4-megabit 2.7-volt Only Serial DataFlash	4 M		7ms Typical	2.7V~3.6V	28P/SOIC
22469	AT45DB081A-TC	ATMEL	each 10MHz 2.7- 3.6V 8 M2.7V OnlySerial DataFlash	8 M				32P/TSOP
18934	AT49BV512-12JC	ATMEL	Single 2.7-volt Battery-Voltage Flash Memory	512K	64K*8	120ns	2.7V	32P/PLCC
18935	AT49F002NT-70JC	ATMEL	2-Megabit(256K x 8) 5-volt OnlyCMOS Flash Memory	2 M	256K*8	70ns	5V	32P/PLCC
8811	AT49F002NT-70PC	ATMEL	2-Megabit(256K x 8)5-volt only CMOS flash memory	2 M	256K*8	70ns	5V	32P/DIP
18936	AT49F002NT-90PC	ATMEL	2-Megabit(256K x 8) 5-volt OnlyCMOS Flash Memory	2 M	256K*8	90ns	5V	32P/DIP
18937	AT49F002NT-90TC	ATMEL	2-Megabit(256K x 8) 5-volt Only CMOSFlashMemory	2 M	256K*8	90ns	5V	32P/TSOP
8808	AT49F010-90JC	ATMEL	1-Megabit(128K x 8) 5-volt only CMOSflashmemory	1 M	128K*8	90ns	5V	32P/PLCC
8807	AT49F020-70JC	ATMEL	2-Megabit (256K x 8) 5-volt onlyCMOS flash memory	2 M	262144*8	70ns	5V	32P/PLCC
16291	AT49F040-90JC	ATMEL	4-megabit (512Kx8) 5-volt Only Flash Memory	4 M	512K*8	90ns	5V	32P-PLCC
18888	AT49F040-90JI	ATMEL	FLASH	4 M	512K*8	90ns	5V	32P/PLCC
18889	AT49F8192-90TC	ATMEL	8-Megabit(512K x 16) 5-volt Only Flash Memory	1 M	128K*8	90ns	5V	48P/TSOP
23539	AT49LV040-90JC	ATMEL	Battery-VoltageFlash Memory	4M	512K*8	70ns	2.7V	32P/PLCC
23542	AT89C55WD-24JI	ATMEL	Microcontroller with 20K Bytes Flash		256**Bit		4~5.5V	44P/PLCC
18890	CAT28F020N-12	CATALYST	FLASH	2 M	128K*8	120ns	5V	32P/PLCC
17499	DA0064M		DiskOnModule	64MB				
18891	DA28F320J5-120	INTEL	5 Volt IntelStrataFlashR Memory	32M	128K	120ns	5V	56P/SSOP
12818	DT28F160S5-70	INTEL	Word-wide FlashFile memory	16M	2M*8/1M*16	75ns	5V	56P-SSOP
12580	E28F002BV-B60ES	INTEL	2-Mbit SmartVoltageboot block flash memory family	2Mb	256K*8	60ns	5V	40P-TSOP
12583	E28F002BV-T60ES	INTEL	2-Mbit SmartVoltageboot blockflash memoryfamily	2Mb	256K*8	60ns	5V	40P-TSOP
12718	E28F004B5B60	INTEL	Smart 5boot blockflash memory4 Mbit	4 M	512K*8	60ns	5V	40P-TSOP
12721	E28F004B5T60	INTEL	Smart5 bootblock flash memory 4Mbit.	4 M	512K*8	60ns	5V	40P-TSOP
12911	E28F004BV-B60ES	INTEL	4-Mbit SmartVoltageboot block flash memory family	4 M	512K*8	60ns	5V	40P-TSOP
12909	E28F004BVT60ES	INTEL	4-Mbit SmartVoltagebootblockflash memory family.	4 M	512K*8/256K*16	60ns	5V	40P-TSOP
12722	E28F004S3120	INTEL	Smart 3 FlashFile memory 4 Mbit	4 M	512K*8	60ns	5V	40P-TSOP
12719	E28F004S585	INTEL	Byte-widesmart 5 FlashFile memory 4 Mbit	4 M	512K*8	85ns	5V	40P-TSOP
18893	E28F008SA-120	INTEL	5 Volt Intel StrataFlashR Memory	8 M	64K	120ns	5V	40P/TSOP
18892	E28F016S3-120	INTEL		16M	128K	70ns	5V	TSOP
18894	E28F016SA-70	INTEL	Word-wideFlashFilememory	16M	2M*8/1M*16	70ns	5V	56P-TSOP
12872	E28F016XD-85	INTEL	16-Mbit (1 Mbit x16) DRAM-interface flash memory	16M	1M*16	85ns	5V	56P-TSOP
18895	E28F128J3-A150	INTEL	4-Mbit SmartVoltageboot blockflash memory family	128M	512K*8/256K*16	60ns	5V	48P/TSOP
12579	E28F200BV-B60ES	INTEL	2-Mbit SmartVoltageboot blockflash memoryfamily	2 M	256K*8/128K*16	60ns	5V	56P/TSOP
12582	E28F200BV-T60ES	INTEL	2-Mbit SmartVoltagebootblockflash memoryFamily	2 M	256K*8/128K*16	60ns	5V	56P/TSOP
12581	E28F200CV-B60ES	INTEL	2-Mbit SmartVoltageBootBlockFlash Memory Family	2 M	256K*8	60ns	5V	48P/TSOP
12571	E28F200CV-T60ES	INTEL	2-Mbit SmartVoltage bootblock flash memory family	2 M	256K*8/128K*16	60ns	5V	48P/TSOP
18896	E28F320J3A-110	INTEL	32 MegabitIntel StrataFlashR Memory	32M	340*161	110ns	5V	56P/TSOP



MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	Access time	Supply Volt.	Pins/Package
12720	E28F400B5B60	INTEL	Smart5 bootblock flash memory 4 Mbit	4M	512K*8/256K*16	60ns	5V	48P/TSOP
12871	E28F400B5B80	INTEL	Smart 5 bootblock flash memory 4 Mbit.	4M	512K*8	80ns	5V	48P/TSOP
12819	E28F400B5T60	INTEL	Smart5 bootblock flash memory	4M	512K*8/256K*16	60ns	5V	56P/TSOP
12820	E28F400B5T80	INTEL	Smart5 bootblock flash memory 4 Mbit	4M	512K*8/256K*16	60ns	5V	56P/TSOP
12907	E28F400BV-T60ES	INTEL	4-Mbit SmartVoltage bootblock flash memory family.	4M	512K*8/256K*16	60ns	5V	56P/TSOP
12908	E28F400CV-B60ES	INTEL	4-Mbit SmartVoltage bootblock flash memory family	4M	512K*8/256K*16	60ns	5V	48P/TSOP
12910	E28F400CV-T60ES	INTEL	4-Mbit SmartVoltage bootblock flash memory family	4M	512K*8/256K*16	60ns	5V	48P/TSOP
18897	E28F800CVT-70	INTEL	FLASH	8M	512*16	70ns	5V	48P/TSOP
18898	F28F010C-90	INTEL	FLASHMEMORY	1M	128K*8	90ns	5V	32P/TSOP
18899	GT28F800B3-B90	INTEL	FLASH	8M	1024*8	90ns	3V	40P/TSOP
22624	IS28F010-45PL	ISSI	131,072x 8CMOS FLASH MEMORY			45nS	-0.2~7V	32P/PLCC
15531	IS28F010A-45W	ISSI	"ISSI" FLASH memory	1Mb	128K*8	45ns	5V	32P/DIP
16897	K9F6408UOC-TCBO	SAMSUNG	Flash		8M*8	50ns	2.7V	44P/TSOP
18938	KM29N040T	SAMSUNG	FLASH	4M				TSOP
18939	LH28F008SAT-85	SHARP	FLASHMEMORY	8M	1MB*8	85ns	5V	40P/TSOP
18940	LH28F008SCHT-TL12	SHARP	8M(X8)FLASH MEMORY	8M	8M*8	120ns	5V	40P/TSOP
18941	LH28F160S3T-L10	SHARP	16M(x8/x16)FLASH MEMORY	16M	2M*8	100ns	2.7V	56P/TSOP
18942	LH28F160S5HNS-L70	SHARP	16M(x8/x16)FLASH MEMORY	16M	2M*8	70ns	2.7V	56P/SSOP
18944	LH28F160S5TL-10A	SHARP	16 M-bit Smart5 Flash Memories(Fast flash Memory)	16M	2M*8/1M*16	100ns	5V	56P/TSOP
18944	LH28F160S5TL-10A	SHARP	16 M-bit Smart 5 Flash Memories(Fast Programming)	16M	2M*8/1M*16	100ns	5V	56P/TSOP
18945	LH28F800BVHE-BTL90	SHARP	8M-BIT(1Mbit*8/512Kbit*16) Smart3 Flash MEMORY	8M	1M*8/512K*16	90ns	2.7V	48P/TSOP
18946	LH28F800SUT-10	SHARP	8M-BIT(1Mbit*8/512Kbit*16) Smart3 Flash MEMORY	8M		100ns		
23371	M25P10-AVMN6	ST(SGS)	Low Voltage, SerialFlash Memory With 40MHz SPI Bus Interface	1Mbit	128*8		2.7~3.6V	8P/SOIC
26835	M25P40VMN6	ST(SGS)	Low Voltage, SerialFlash Memory With 25MHz SPI Bus Interface	512Kbit	128*4		2.7~3.6V	8P/SO
18948	M28F101-100N1	ST(SGS)	Memory configuration 128Kx8 Memory type Flash Memory size 1M-bit 1Mb FLASH memory	1M	128K*8	100ns	5V	32P/TSOP
1536	M28F101-150P1	ST(SGS)	Memory configuration 128Kx8 Memory type Flash Memory size 1M-bit 1Mb FLASH memory	1M	128K*8	150ns	5V	32P/DIP
18949	M28F201-120K1	ST(SGS)	FLASH			120ns	5V	32P/PLCC
18950	M28F201-150K1	ST(SGS)	FLASH			150ns	5V	32P/PLCC
22700	M28F512-12C1	ST(SGS)	FLASHMEMORY	512K	64K*8	120nS	-0.6~7V	32P/PLCC
23573	M29F010B-120K1	ST(SGS)	Single Supply Flash Memory	1M	128Kb*8	120ns	5V±0%	32P/PLCC
23574	M29F010B-90K1	ST(SGS)	Single Supply Flash Memory	1M	128Kb*8	90ns	5V±0%	32P/PLCC
16608	M29F040B-70K1	ST(SGS)	4 Mbit Single Supply Flash Memory	4M	512K*8	70ns	5V	32P/PLCC
22204	M29F040B-70K6	ST(SGS)	4Mbit Single Supply Flash Memory	4M	512K*8	70ns	5V	32P/PLCC
18951	M29F040B-90K1	ST(SGS)	4Mbit Single Supply Flash Memory	4M	512K*8	90ns	5V	32P/PLCC
23575	M29F040B-90K6	ST(SGS)	Single Supply Flash Memory	4M	512Kb*8	90ns	5V±0%	32P/PLCC
18952	M29F800AB-90N1	ST(SGS)	8 Mbit Single Supply Flash Memory	8M	1M*8/512K*16	90ns	5V	48P/TSOP
18953	M29W160DB-90N1	ST(SGS)	16 Mbit 3V Supply Flash Memory	16M	2M*8/1M*16	90ns	3V	48P/TSOP
23576	M29W160DT-70N1	ST(SGS)	Supply Flash Memory	16M	2M*8/1M*16	70ns	2.7~3.6V	48P/TSOP
23578	M29W160DT-90N1	ST(SGS)	Supply Flash Memory	16M	2M*8/1M*16	90ns	2.7~3.6V	48P/TSOP
23579	M29W160EB-70N6	ST(SGS)	Supply Flash Memory	16M	2M*8.1M*16	70ns	2.7V~3.6V	48P/TSOP
23583	M29W320DB-70N6	ST(SGS)	Supply Flash Memory	32M	4M*8/2M*16	70ns	2.7~3.6V	48P/TSOP
18954	M29W320DB-90N6	ST(SGS)	32 Mbit 3V Supply Flash Memory	32M	4M*8/2M*16	90ns	3V	48P/TSOP
18955	M29W320DT-70N6	ST(SGS)	32Mbit 3V Supply Flash Memory	32M	4M*8/2M*16	70ns	3V	48P/TSOP
23584	M29W800AB-120N1	ST(SGS)	Low Voltage Single Supply Flash Memory	8M	1Mb*8/512Kb*16	120ns	2.7V~3.6V	48P/TSOP
18956	M29W800AB-90N1	ST(SGS)	8 Mbit Low Voltage Single Supply Flash Memory	8M	1M*8/512K*16	70ns	3V	48P/TSOP
18957	M29W800AB-90N6	ST(SGS)	8 Mbit Low Voltage Single Supply Flash Memory	8M	1M*8/512K*16	90ns	3V	48P/TSOP
23585	M29W800DB-70N1	ST(SGS)	Supply Flash Memory	8M	1Mb*8/512Kb*16	70ns	2.7V~3.6V	48P/TSOP
22701	M29W800DT70N6E	ST(SGS)	Supply Flash Memory	8M	1Mb*8	70nS	2.7~3.6V	48P/TSOP
18958	MBM29F040A-12PD	FUJITSU	4M(512K*8) BITFLASH MEMORY	4M	512K*8	120ns	5V	32P/PLCC
18959	MBM29F040A-12PFTN-X	FUJITSU	4M(512K*8) BIT FLASH MEMORY	4M	512K*8	120ns	5V	32P/TSOP
18960	MBM29F080A-90PFTN	FUJITSU	8M(1M*8) BIT FLASH MEMORY	8M	1M*8	90ns	5V	48P/TSOP
18961	MBM29F400TA-90PFTN	FUJITSU	4M(512K*8/256K*16)BIT CMOS FLASH MEMORY	4M	512K*8/256K*16	90ns	5V	48P/TSOP
18962	MBM29LV160BE-70TN	FUJITSU	16M(2M*8/1M*16)BIT CMOS FLASH MEMORY	16M	2M*8/1M*16	70ns	3V	48P/TSOP
23589	MBM29LV160TE-70TN	FUJITSU	FLASHMEMORY	16M	2M*8/1M*16	70ns	3V	48P/TSOP
23590	MBM29LV400B-10PFTN	FUJITSU	FLASHMEMORY	4M	512K*8/256K*16	120ns	3V	48P/TSOP
23591	MBM29LV400BC-70PFTN	FUJITSU	FLASHMEMORY	4M	512K*8/256K*16	120ns	3V	48P/TSOP
23592	MBM29LV800BA-70PFTN	FUJITSU	FLASHMEMORY	8M	1M*8/512K*16	90ns	3V	48P/TSOP
22751	MX28F1000PQC-12C4	MXIC	CMOS FLASHMEMORY	1M	128K*8	120ns	5V	32P/PLCC
22752	MX28F2000PQC-12C4	MXIC	CMOS FLASHMEMORY	2M	256K*8	120nS	-0.5~7V	32P/PLCC
18963	MX28F2000QC-12C4	MXIC	FLASH			120ns		PLCC
22753	MX29F002TQC-12	MXIC	CMOS FLASH MEMORY	2M	256K*8	120nS	5V	32P/PLCC
22754	MX29F002TQC-90	MXIC	CMOS FLASHMEMORY	2M	256K*8	90ns	5V	32P/PLCC
22764	MX29F040QC-12	MXIC	CMOS EQUALSECTOR FLASHMEMORY	4M	512K*8	120nS	-0.5~7V	32P/PLCC
22765	MX29F040QC-90	MXIC	CMOS EQUALSECTOR FLASH MEMORY	4M	512K*8	90nS	-0.5~7V	32P/PLCC
23594	MX29LV160ABTC-70	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	16M	2M*8/1M*16	70ns	3.0V	48P/TSOP



MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	AccessTime	SupplyVolt.	Pins/Package
18964	MX29LV160ABTC-90	MXIC	FLASH			90ns		48P/TSOP
23595	MX29LV160ATTC-90	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	16M	2M*8/1M*16	90ns	2.7~3.6V	48P/TSOP
18968	MX29LV320ABTC-90	MXIC	32M-BIT SINGLE VOLTAGE 3V ONLY FLASH MEMORY	32M	4M*8/2M*16	90ns	3V	48P/TSOP
23596	MX29LV800BTC-70	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	8M	1M*8/512K*16	70ns	3.0V	48P/TSOP
23597	MX29LV800BTC-90	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	8M	1M*8/512K*16	90ns	3.0V	48P/TSOP
23598	MX29LV800TTC-90	MXIC	CMOS SINGLE VOLTAGE 3V ONLY FLASH MEMORY	8M	1M*8/512K*16	90ns	3.0V	48P/TSOP
18969	N28F001BXT-150	INTEL	FLASH			150ns		32P/PLCC
18970	N28F010-120	INTEL	FLASH			120ns		32P/PLCC
18971	N28F020-120	INTEL	FLASH	2M				PLCC
18972	N28F020-150	INTEL	FLASH	2M				32P/PLCC
18973	P28F001BXT-150	INTEL	FLASH	1M				32P/DIP
12823	PA28F008S585	INTEL	Byte-wide smart 5 Flash File memory 8Mbit	8M	1M*8	85ns	5V	44P/PSOP
12808	PA28F016S3120	INTEL	Smart 3 Flash File memory 16 Mbit.	16M	2M*8/1M*16	120ns	3.3V	44P/PSOP
12814	PA28F016S585	INTEL	Byte-wide smart 5 Flash File memory 16 Mbit.	16M	2M*8/1M*16	85ns	5V	44P/PSOP
12578	PA28F200B5-T60	INTEL	Smart 5 boot block flash memory 2Mbit.	2M	256K*8	60ns	5V	44P/PSOP
12874	PA28F400B5B60	INTEL	Smart 5 boot block flash memory 4 Mbit.	4M	512K*8/256K*16	60ns	5V	44P/PSOP
12873	PA28F400B5B80	INTEL	Smart 5 boot block flash memory 4 Mbit.	4M	512K*8/256K*16	80ns	5V	44P/PSOP
12822	PA28F400B5T60	INTEL	Smart 5 boot block flash memory 4 Mbit.	4M	512K*8/256K*16	80ns	5V	44P/PSOP
12821	PA28F400B5T80	INTEL	Smart 5 boot block flash memory 4 Mbit	4M	512K*8/256K*16	80ns	5V	44P/PSOP
18977	PA28F800B5-B70	INTEL	FLASH	8M			5V	SOP
18978	PA28F800B5-T70	INTEL	FLASH	8M				SOP
18979	RC28F128J3C150	INTEL	FLASH					BGA
18980	SST28SF040A-90-4C-PH	SST	4Mbit (512K x8) SuperFlash EEPROM	4M	512K*8	90ns	5V	32P/DIP
18981	SST29EE010-120-4C-NH	SST	1Mbit (128K x8) Page-Write EEPROM	1M	128K*8	120ns	5V	32P/PLCC
18982	SST29EE010-90-4C-NH	SST	1Mbit (128K x8) Page-Write EEPROM	1M	128K*8	90ns	5V	32P/PLCC
18983	SST29LE512-150-4C-NH	SST	1 Mbit (128K x8) Page-Write EEPROM	1M	128K*8	150ns	3V	32P/PLCC
18984	SST39SF010-90-4C-NH	SST	1 Mbit (x8) Multi-Purpose Flash	1M	128K*8	90ns	5V	32P/PLCC
18985	SST39SF020-90-4C-PH	SST	2 Mbit (x8) Multi-Purpose Flash	2M	256K*8	90ns	5V	32P/DIP
16611	SST39SF020A-70-4C-NH	SST	"SST" 2Mbit (x8) Multi-Purpose Flash	2M	128K*8	70ns	5V	32P/PLCC
16612	SST39SF020A-70-4C-PH	SST	Multi-purpose flash	2M	128K*8	70ns	5V	32P/DIP
18986	SST39SF512-70-4C-NH	SST	512 Kbit (x8) Multi-Purpose Flash		512K*8	70ns	5V	32P/PLCC
18987	SST39SF512-90-4C-NH	SST	512 Kbit (x8) Multi-Purpose Flash		512K*8	90ns	5V	32P/PLCC
23604	SST39VF010-70-4C-WH	SST	Multi-Purpose Flash	1M		70ns	2.7~3.6V	32P/TSOP
22838	SST39VF010-90	SST	Multi-Purpose Flash	1M	128K*8	90ns	2.7~3.6	32P/TSOP
18988	SST39VF020-70-4C-NH	SST	2Mbit (x8) Multi-Purpose Flash	2M	256K*8	70ns	2.7V	32P/PLCC
18989	SST39VF040-70-4C-NH	SST	4Mbit (x8) Multi-Purpose Flash	4M	512K*8	70ns	2.7V	32P/PLCC
28222	SST39VF040-70-4C-WH	SST	4Mbit (x8) Multi-Purpose Flash	4M	512K*8	70ns	2.7V	32P/TSOP
23605	SST39VF512-70-4C-WH	SST	Multi-Purpose Flash	512K		70ns	2.7~3.6V	32P/TSOP
23606	SST39VF800A-70-4C-B3K	SST	Multi-Purpose Flash	8M		70ns	2.7~3.6V	48P/TFBGA
23608	SST39VF800A-70-4C-EK	SST	Multi-Purpose Flash	8M		70ns	2.7~3.6V	48P/TSOP
23609	SST49LF004A-33-4C-NH	SST	Firmware Hub	4M		33MHz	3.0-3.6V	32P/PLCC
24285	SST49LF020A-33-4C-NH	SST	2Mbit LPC flash Flash	2M	256Kx8	120ns	3.0-3.6V	32P/PLCC
18993	T28F160C3BA110	INTEL	FLASH	16M				TSOP
18992	TE28F016B3TA110	INTEL	FLASH	16M				TSOP
18990	TE28F016B3TA90	INTEL	FLASH	16M			3V	TSOP
18991	TE28F128J3C150	INTEL	FLASH					TSOP
23613	TE28F160B3TA110	INTEL	3-Volt Advanced Boot Block Flash Memory	16M		110ns	3V	48P/TSOP
23614	TE28F160C3BA110	INTEL	Boot Block Flash Memory	16M		110ns	3V	48P/TSOP
18994	TE28F160C3BD-70	INTEL	FLASH			70ns		TSOP
23615	TE28F160C3TC-70	INTEL	Boot Block Flash Memory	16M		70ns	3V	48P/TSOP
18995	TE28F160C3TD-70	INTEL	FLASH			70ns		TSOP
12817	TE28F160S375	INTEL	Word-wide Flash File memory	16M	2M*8/1M*16	75ns	5V	56P/TSOP
18996	TE28F320C3BA100	INTEL	FLASH	32M		100ns		TSOP
18997	TE28F320C3BC-70	INTEL	FLASH			70ns		48P/TSOP
23617	TE28F320C3BD70	INTEL	Boot Block Flash Memory	32M		70ns	3.0V	48P/TSOP
23620	TE28F320C3TD-70	INTEL	Boot Block Flash Memory	32M		70ns	3.0V	48P/TSOP
18998	TE28F400B3T110	INTEL	FLASH	4M				TSOP
18999	TE28F640J3C-120	INTEL	FLASH			120ns		TSOP
18974	TE28F800B3BA90	INTEL	FLASH					TSOP
18975	TE28F800B5B-90	INTEL	FLASH					48P/TSOP
18976	TE28F800C3B90	INTEL	Flash Memory	4M	256kbit*16	90ns	2.7~3.6V	TSOP
19000	TMS28F010A-15C4FML	T.I.	1048576-bit Flash Electrically Erasable Programmable Read-only Memory	1M	128K*8	150ns	5.5V	32P/PLCC
19001	TMS28F010B-10C4FMC	T.I.	131072 BY8-BIT FLASH MEMORY	1M	131072*8	100ns	5.5V	32P/PLCC
19002	TMS28F010B-12C4FME	T.I.	131072 BY8-BIT FLASH MEMORY	1M	131072*8	120ns	5.5V	32P/PLCC
19003	TMS28F010B-12C4FML	T.I.	131072 BY8-BIT FLASH MEMORY	1M	131072*8	100ns	5.5V	32P/PLCC



MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	Size	Organisation	AccessTime	SupplyVolt.	Pins/Package
19004	TMS28F010B-12C4FMQ	T.I.	131072BY8-BIT FLASH MEMORY	1M	131072*8	100ns	5.5V	32P/PLCC
19005	TMS28F010B-12C5FME	T.I.	131072BY8-BITFLASH MEMORY	1M	131072*8	120ns	5.5V	32P/PLCC
19006	TMS28F010B-12C5FML	T.I.	131072BY 8-BITFLASH MEMORY	1M	131072*8	120ns	5.5V	32P/PLCC
19007	TMS28F010B-15C4FML	T.I.	131072 BY8-BIT FLASHMEMORY	1M	131072*8	150ns	5.5V	32P/PLCC
19008	TMS28F010B-90C5FML	T.I.	131072BY 8-BITFLASH MEMORY	1M	131072*8	90ns	5.5V	32P/PLCC
23516	TMS28F512A-12C4FMQ	T.I.	5.5 V FLASHMEMORY		65536 by8Bits	120ns		32P/PLCC
19010	TMS28F512A-15C4FME	T.I.	FLASH MEMORY	512K	64K*8	150ns	5.5V	32P/PLCC
19011	TMS28F512A-15C4FML	T.I.	FLASH MEMORY	512K	64K*8	150ns	5.5V	32P/PLCC
11833	TMS28F512A-15FME	T.I.	FLASHMEMORY	512K	64K*8	100ns	5.5V	32P/PLCC
19009	TMS28F512A-15FMQ	T.I.	FLASHMEMORY	512K	64K*8	120ns	5.5V	32P/PLCC
19013	TMS29F002RT-12BFML	T.I.	262144 BY 8-BIT FLASH MEMORIES	2M	26144*8	120ns	5V	32P/PLCC
19014	TMS29F040-12C5DDE	T.I.	524288 BY 8-BIT FLASH MEMORY	4M	524288*8	120ns	5V	32P/TSOP
19017	TMS29F040-12C5DDL	T.I.	524288 BY 8-BIT FLASH MEMORY	4M	524288*8	120ns	5V	32P/TSOP
19018	TMS29F040-12C5FME	T.I.	524288 BY 8-BIT FLASH MEMORY	4M	524288*8	120ns	5V	32P/PLCC
19019	TMS29F040-90C5DDE	T.I.	524288 BY 8-BIT FLASH MEMORY	4M	524288*8	90ns	5V	32P/TSOP
19020	TMS29F040-90C5DDL	T.I.	524288 BY 8-BIT FLASH MEMORY	4M	524288*8	90ns	5V	32P/TSOP
19021	TMS29F040-90C5FML	T.I.	524288 BY 8-BIT FLASH MEMORY	4M	524288*8	90ns	5V	32P/PLCC
10946	W29C011A-15	WINBOND	128K*8 CMOS flash memory	1M	128K*8	150ns	5V	32P/DIP
14148	W29C020C-90B	WINBOND	256K*8 CMOS flash memory	2M	256K*8	90ns	5V	32P/DIP
11825	W29C020CP-90B	WINBOND	256K*8 CMOS flash memory	2M	256K*8	90ns	5V	32P/PLCC
19023	W29C020CT-90B	WINBOND	128K*8 CMOS flash memory	2M	128K*8	90ns	5V	32P/TSOP
10947	W29C040-90B	WINBOND	512K*8 CMOS flash memory	4M	512K*8	90ns	5V	32P/DIP
17704	W29C040P-70B	WINBOND	512K*8 CMOS flash memory	4M	512K*8	70ns	5V	32P/PLCC
22881	W29C040P-90	WINBOND	512K*8 CMOS flash memory	4M	512K*8	90ns	5V	32P/PLCC
19024	W29EE011P-90	WINBOND	128K*8 CMOS flash memory	1M	128K*8	90ns	5V	32P/PLCC

動態式記憶體 D-RAM

詳細產品規格--請點擊www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	Pins	Organisation	AccessTime	Size(bits)	Package
23413	HY57V281620HCT-7	HYNIX	SynchronousDRAM	54P	4 Banks*2M*16bits	143MHz		TSOP
22625	IS42S16100-7T	ISSI	SYNCHRONOUS DYNAMIC RAM	50P	16Mb Synchronous DRAM	166,143,100MHz	512K*16bits	TSOP
23593	MSM514400D-60SJ	OKI	DYNAMICRAM	26P		60ns	1,048,576*4Bit	SOJ

VIDEO-RAM

詳細產品規格--請點擊www.100y.com.tw

PartNo.	ProductNo.	Manuf.	Description	Organisation	AccessTime	Size(bits)	PinsPackage
23691	W9968CF	WINBOND	JPEG USB Dual Mode CameraChip	1K	13.5 MHz	128*8	128P/QFP

